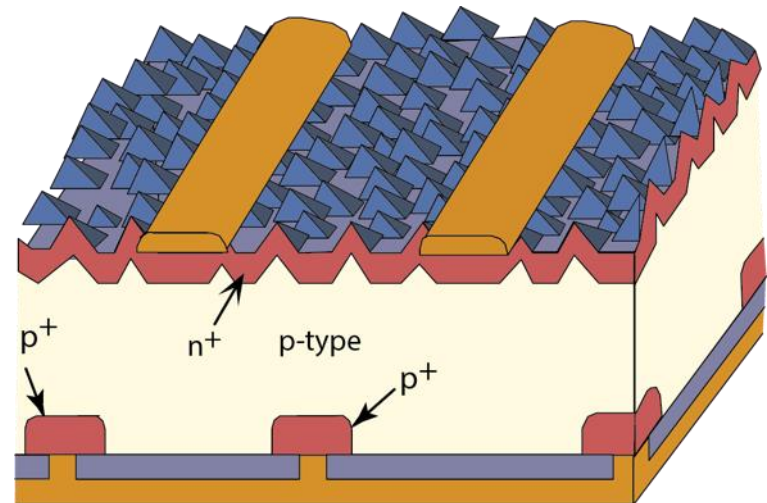
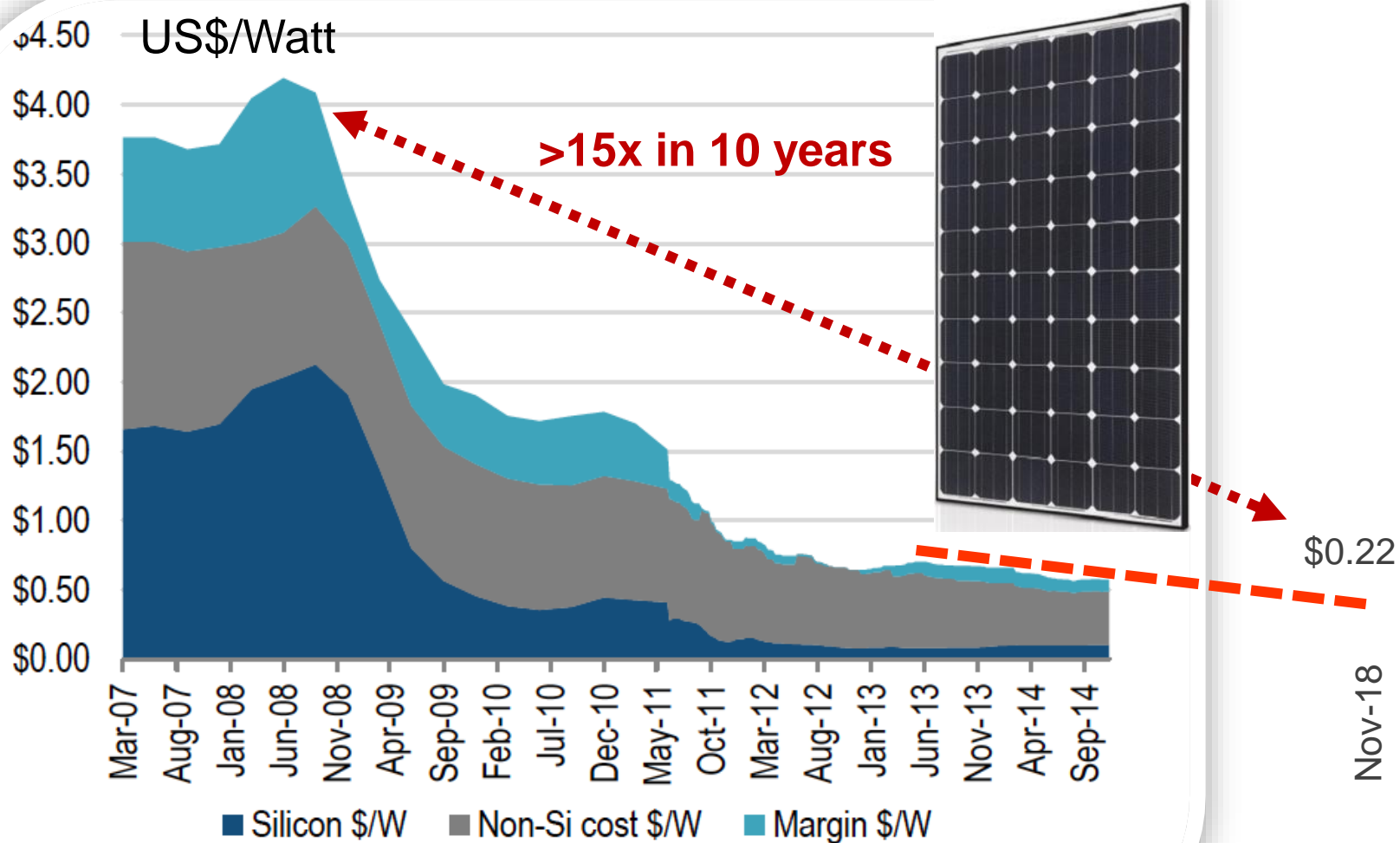


# "What's next in photovoltaics, beyond PERC?"

Martin A. Green, UNSW Sydney

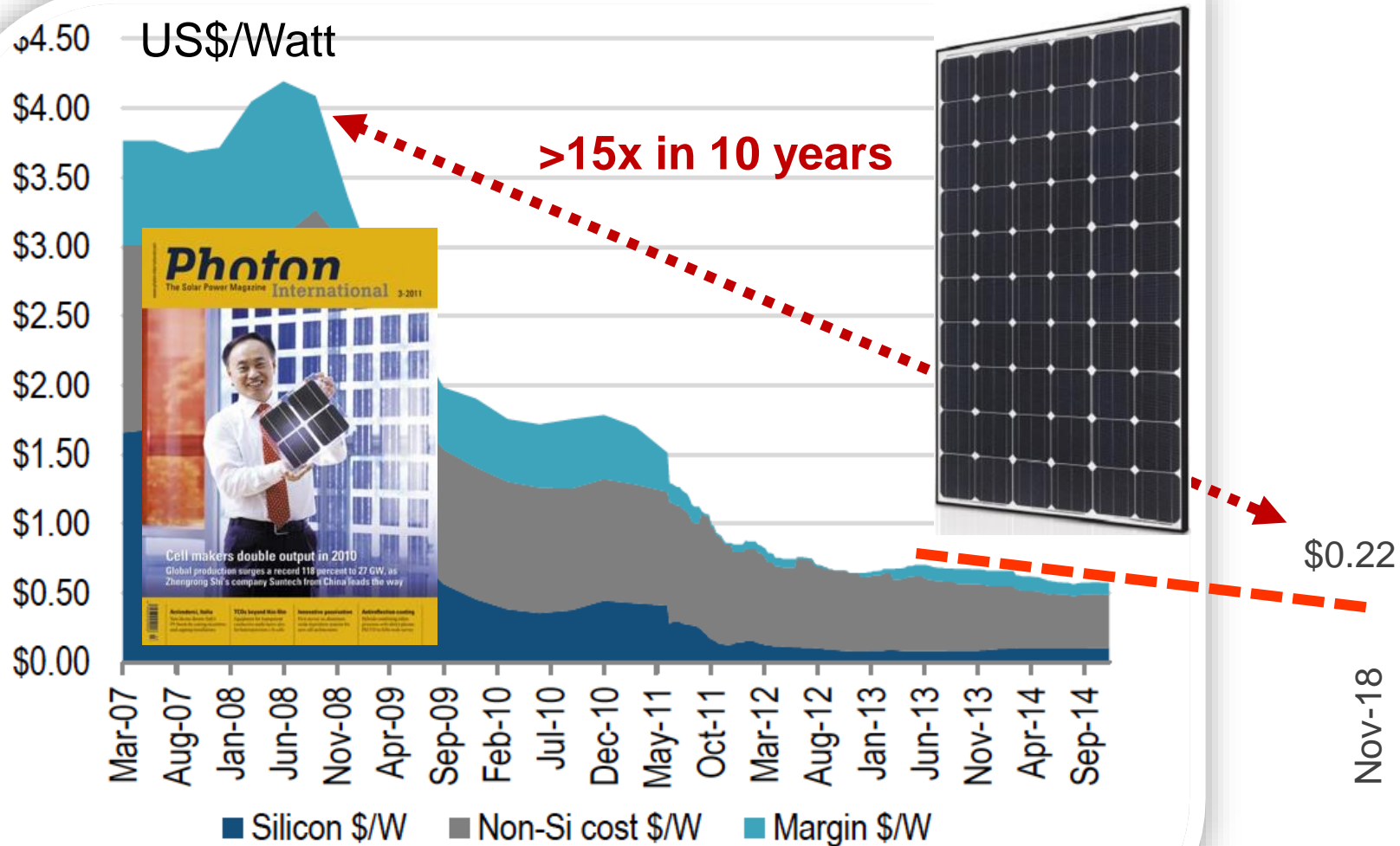


# Recent cost reductions



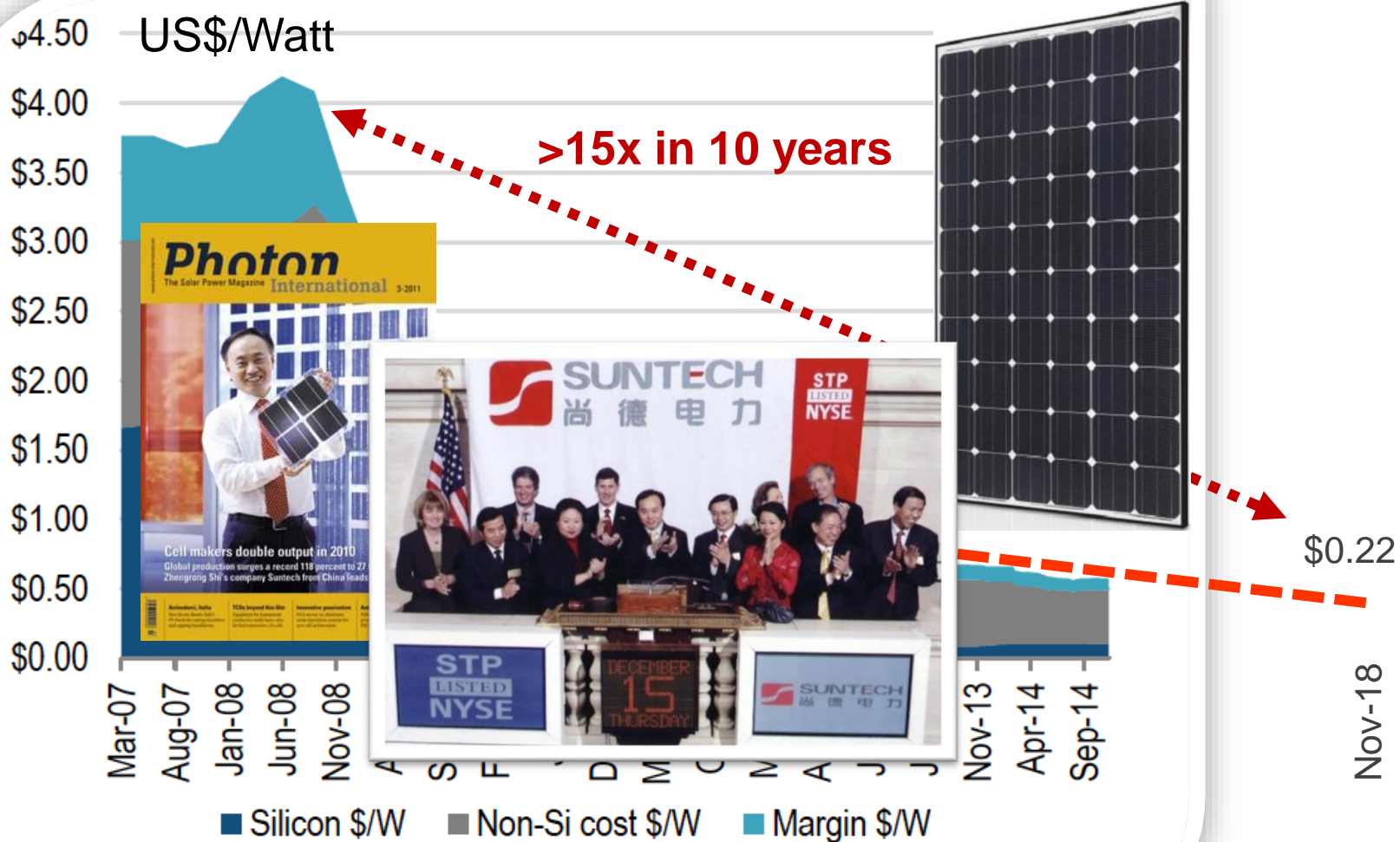
Source: EnergyTrend, Company data, Credit Suisse estimates.

# Recent cost reductions



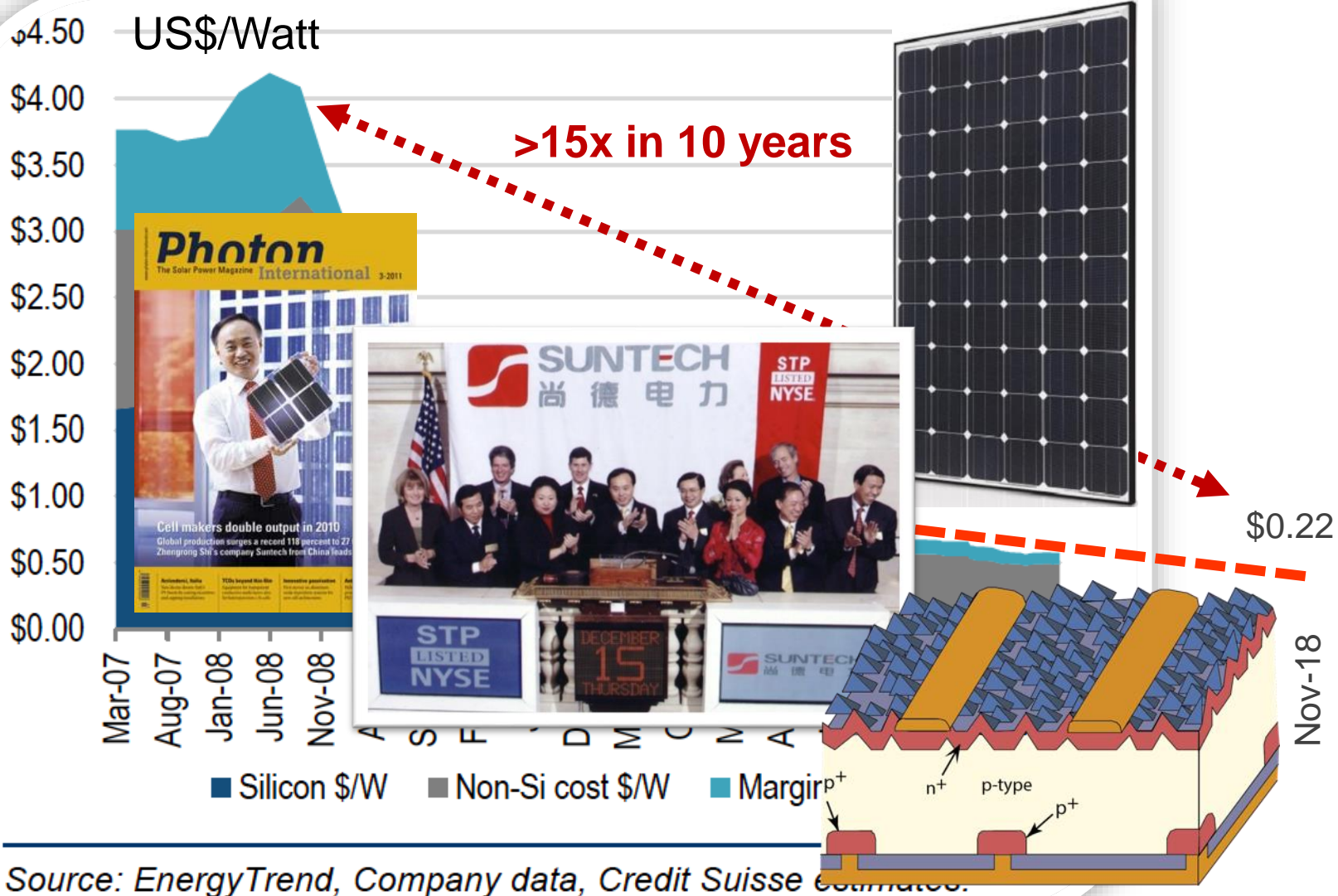
Source: EnergyTrend, Company data, Credit Suisse estimates.

# Recent cost reductions

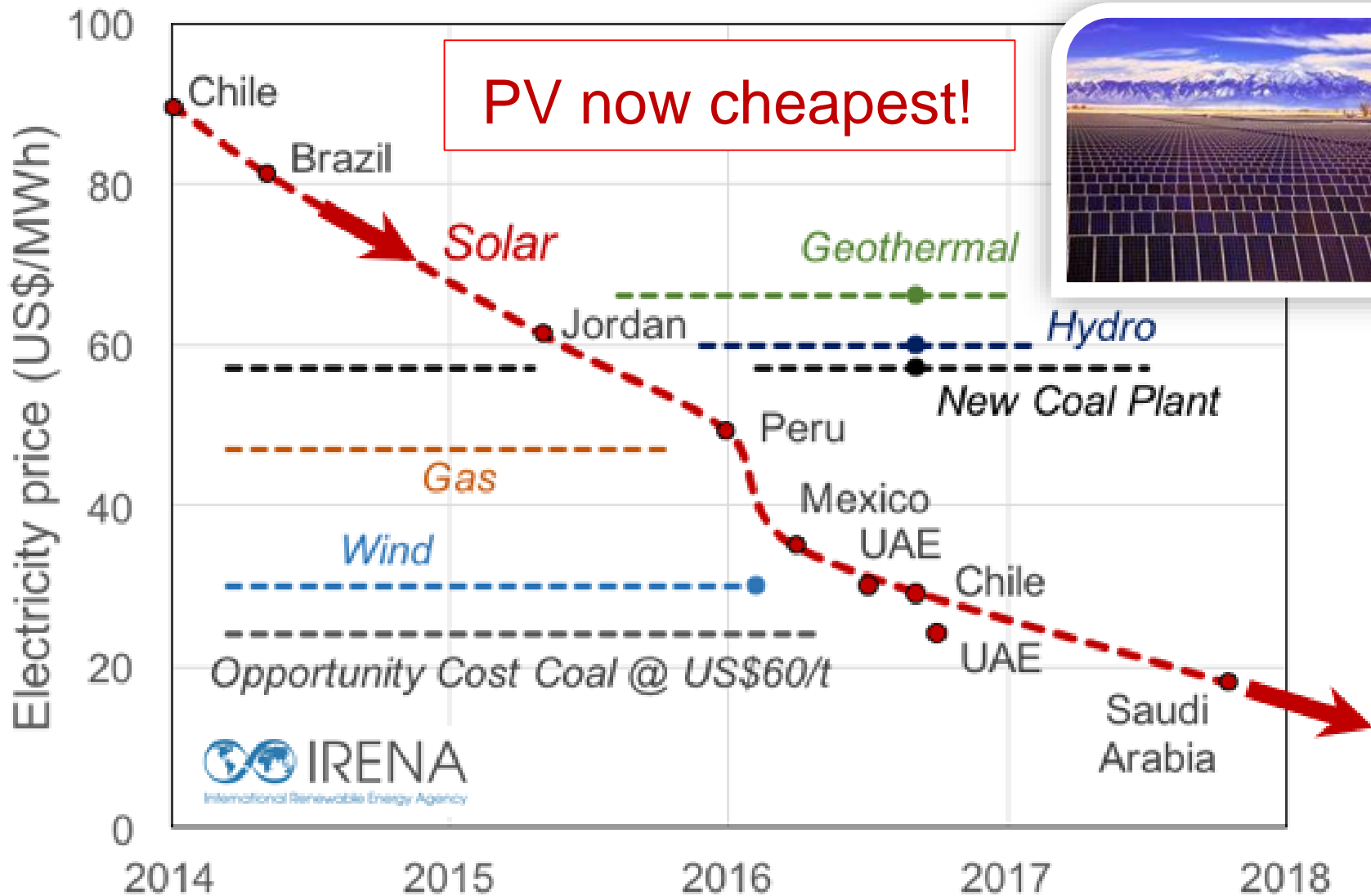


Source: EnergyTrend, Company data, Credit Suisse estimates.

# Recent cost reductions

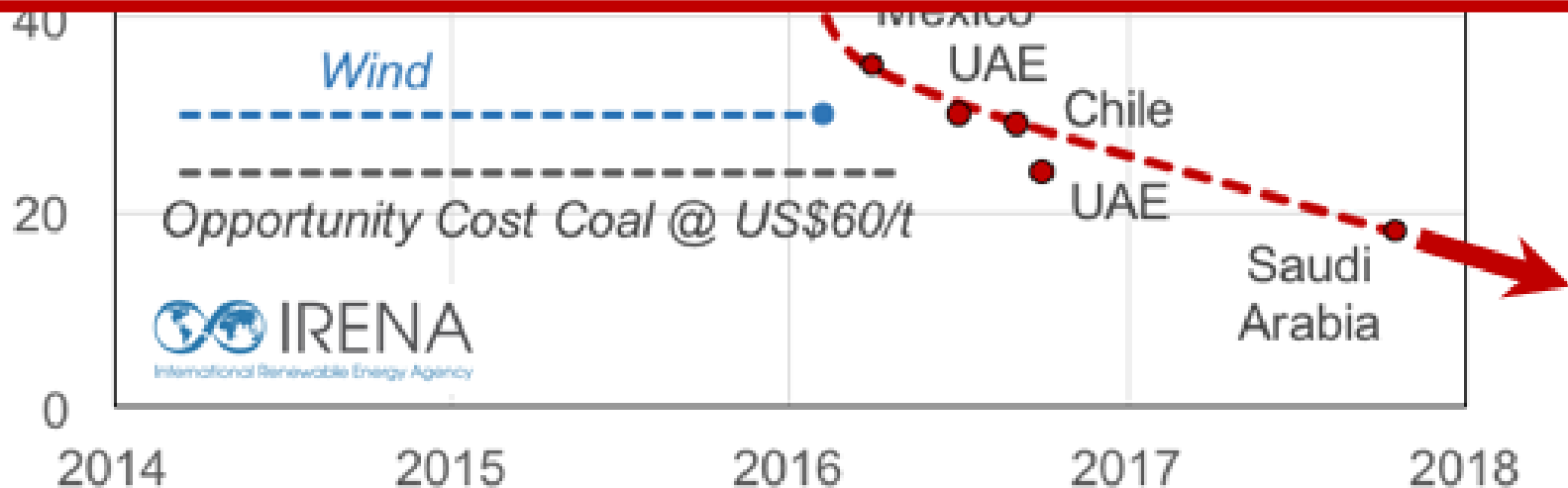


# Low Bids: International Electricity Auctions



# The myth of cheap coal– 35% of coal capacity costs more to run than building new renewables in 2018, increasing to 96% by 2030

Electricity price (US\$/MWh)



# The myth of cheap coal– 35% of coal capacity costs more to run than building new renewables in 2018, increasing to 62% by 2020

Electricity price (US\$/MWh)

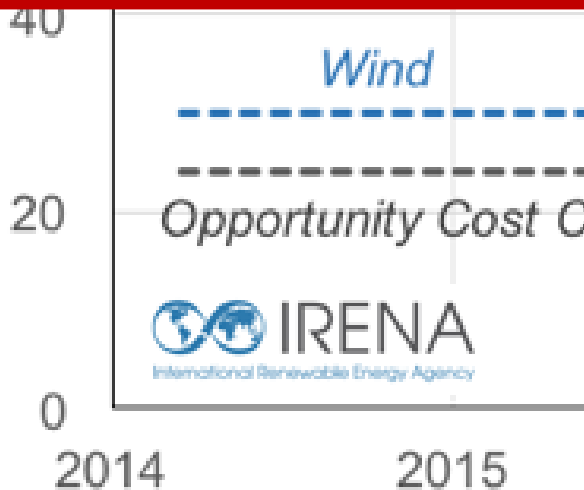


Figure 2: Short-run cost of coal versus levelized cost of electricity of wind and solar



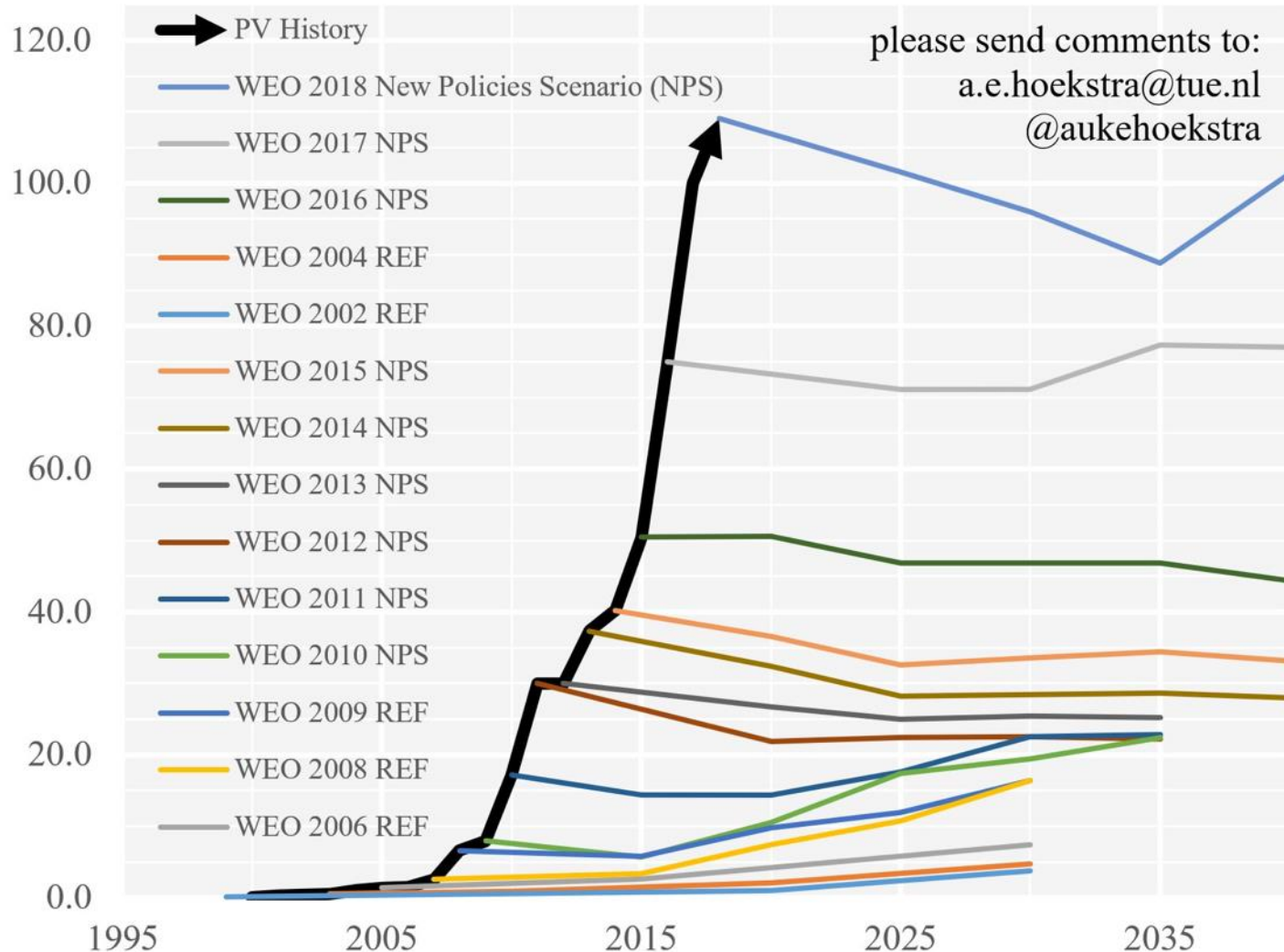
BNEF



# PV market growing quickly (> 0.1 TW in 2017)

## Annual PV additions: historic data vs IEA WEO predictions

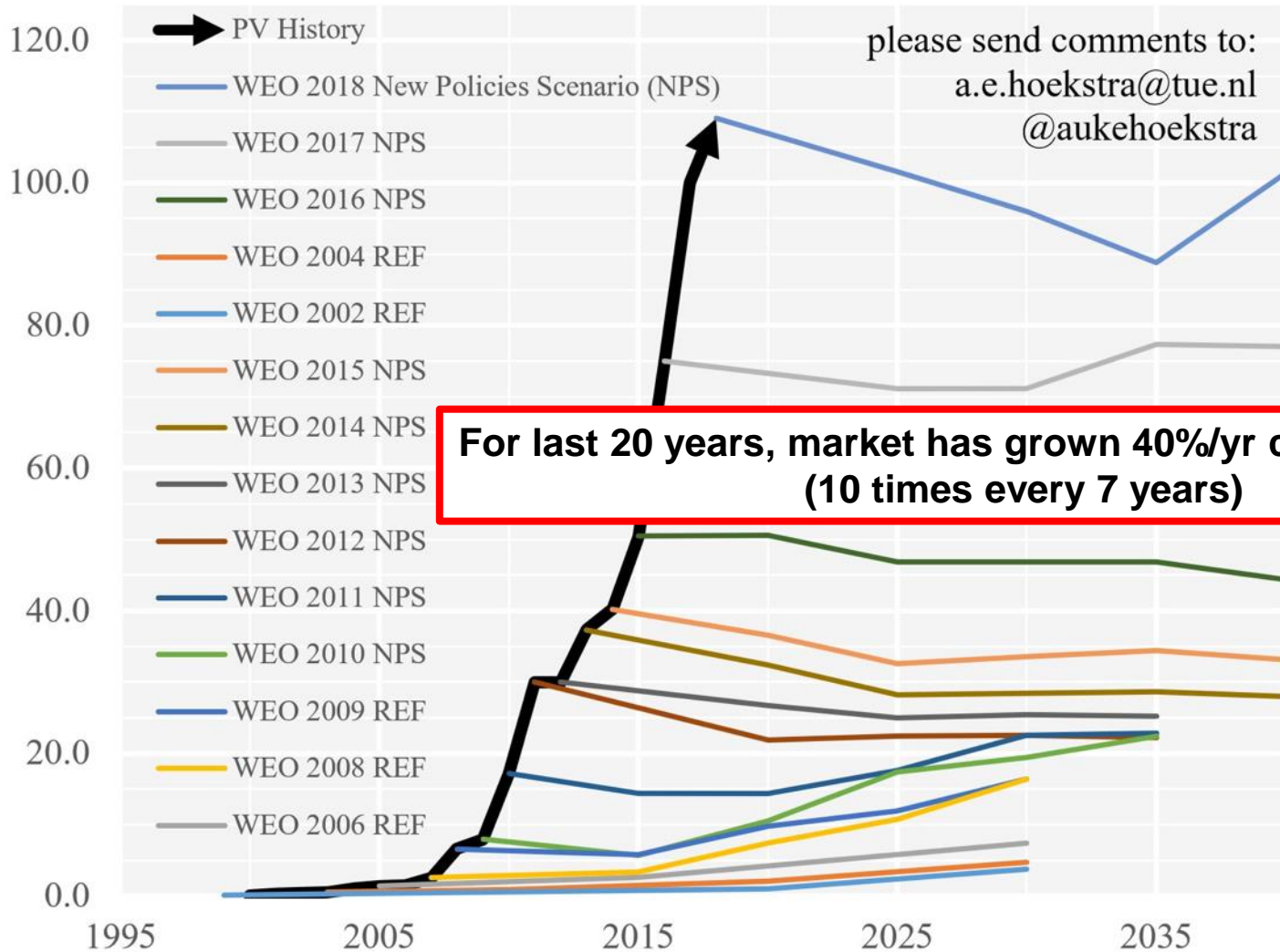
In GW of added capacity per year - source International Energy Agency - World Energy Outlook

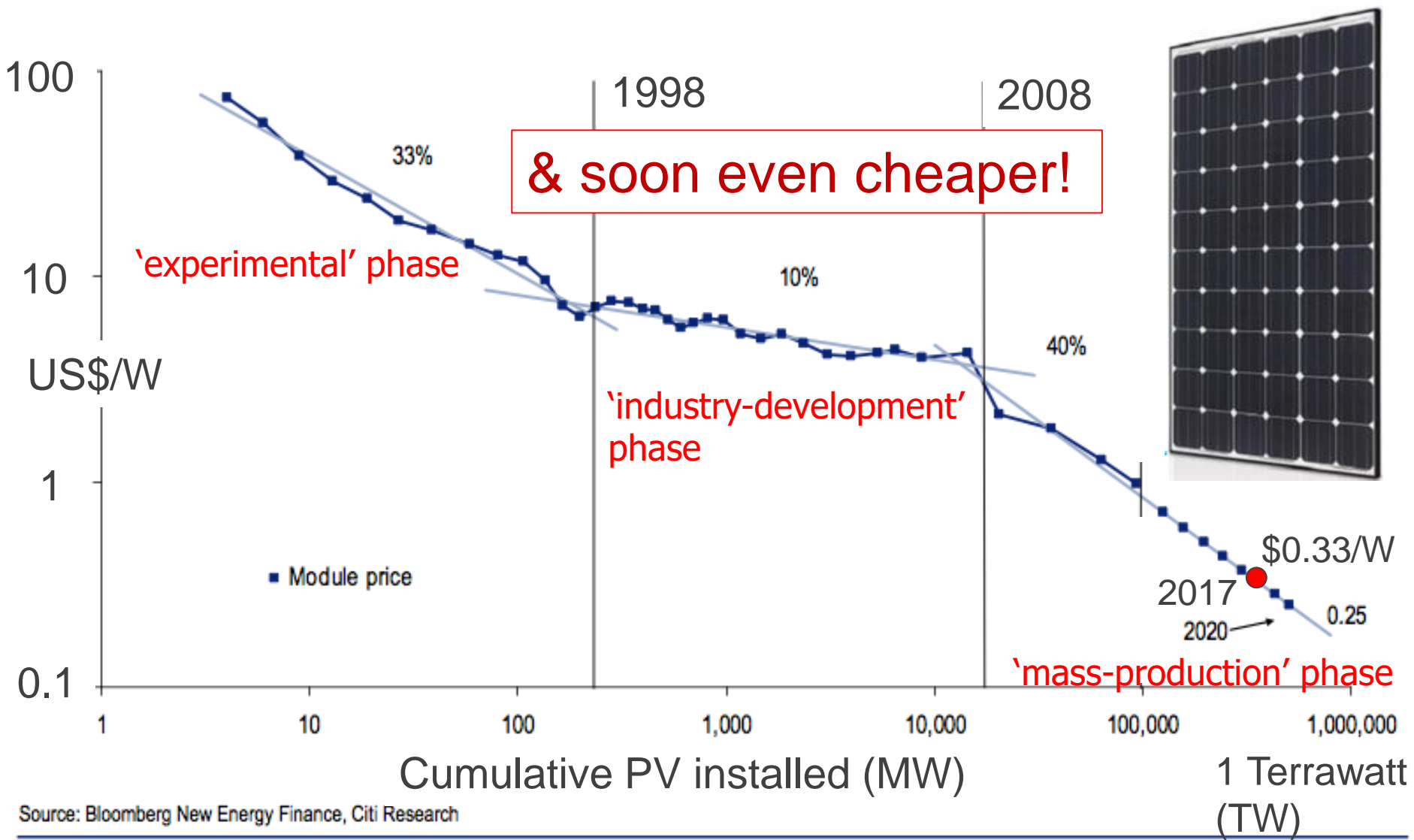


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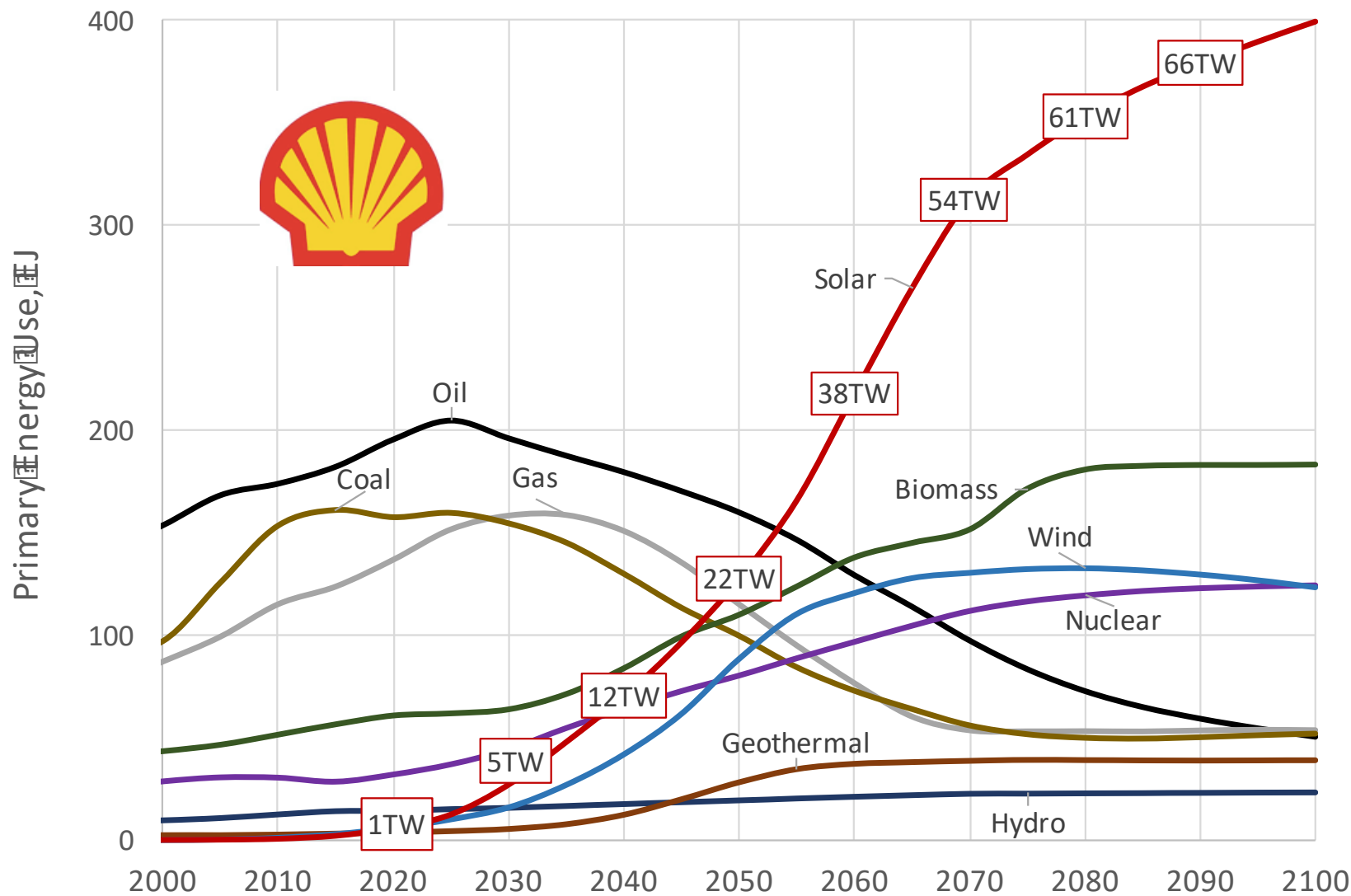
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In GW of added capacity per year - source International Energy Agency - World Energy Outlook





# Primary energy use in Shell's "Sky" scenario (26 March 2018)

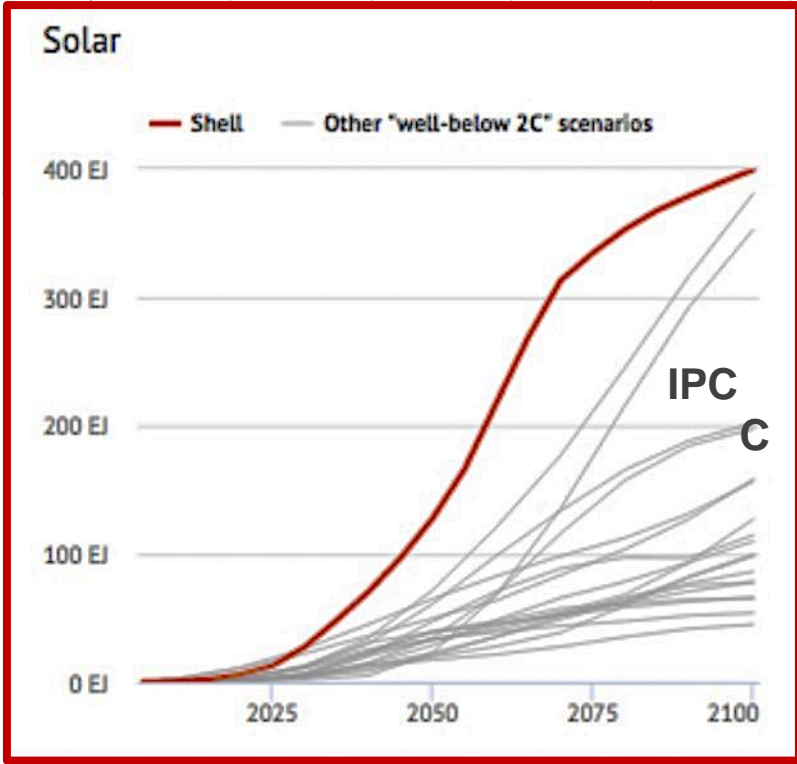
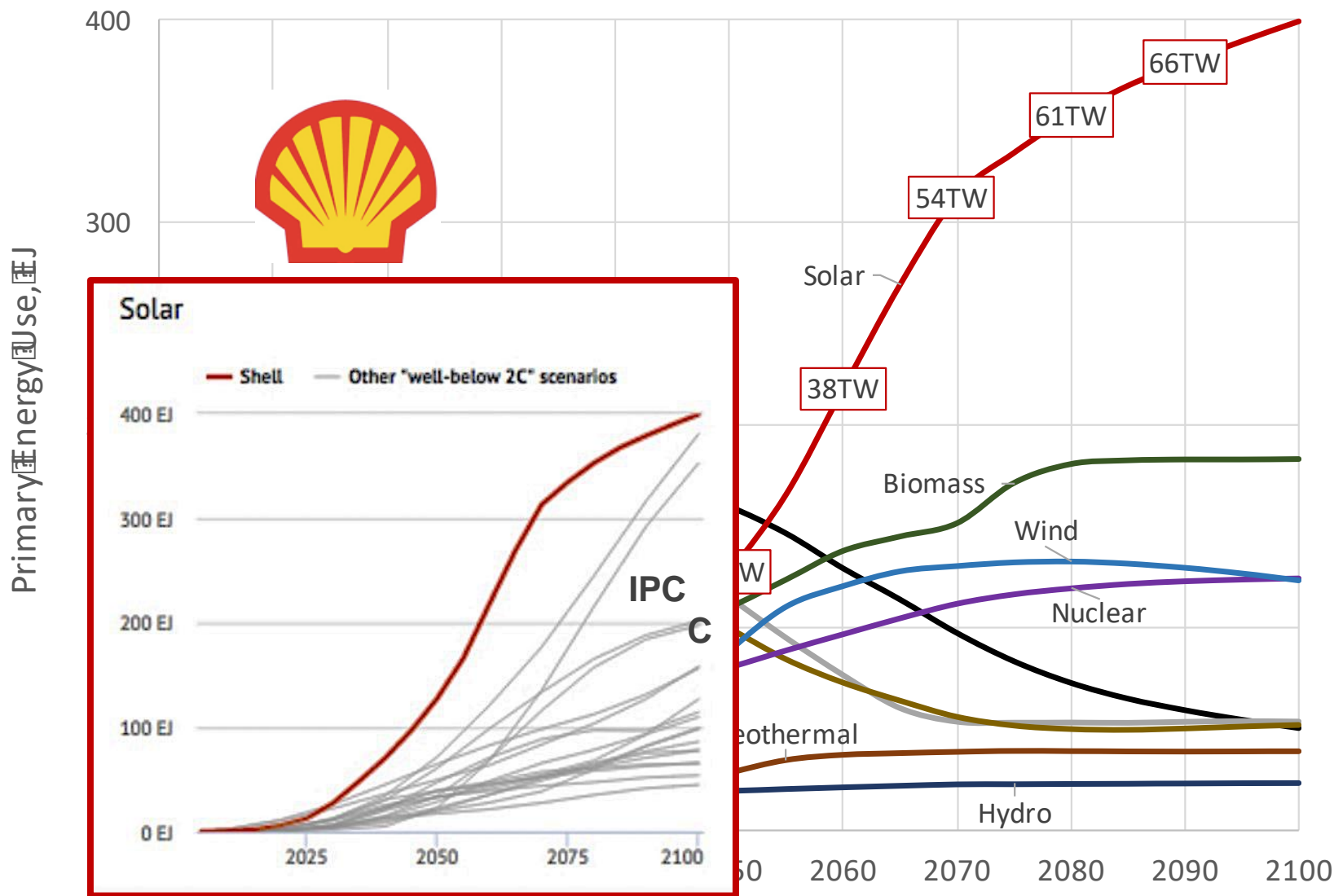


Includes waste energy oil, coal, gas, bioenergy, nuclear; only generated energy wind, solar



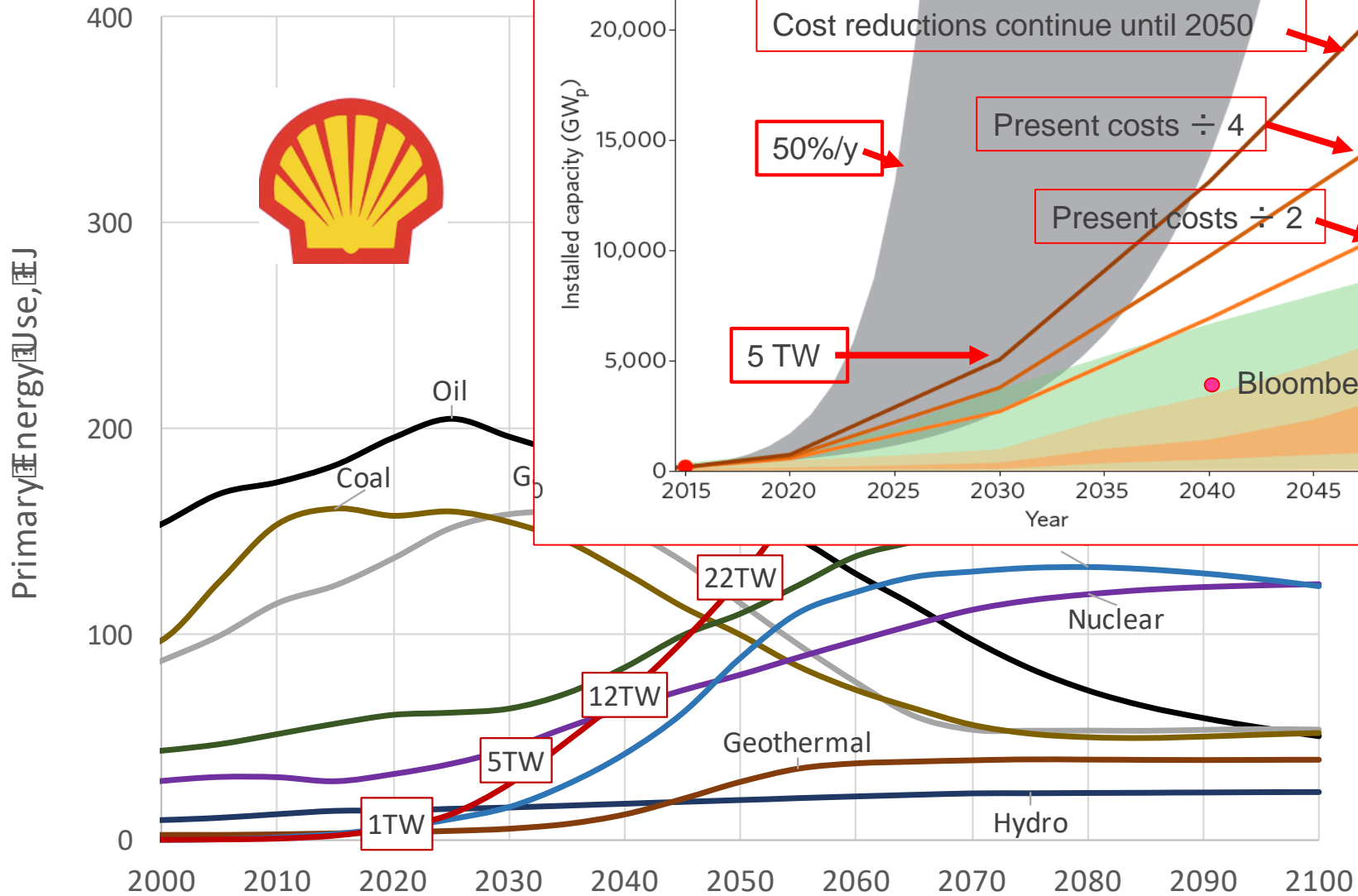
UNSW  
SYDNEY

# Primary energy use in Shell's "Sky" scenario (26 March 2018)



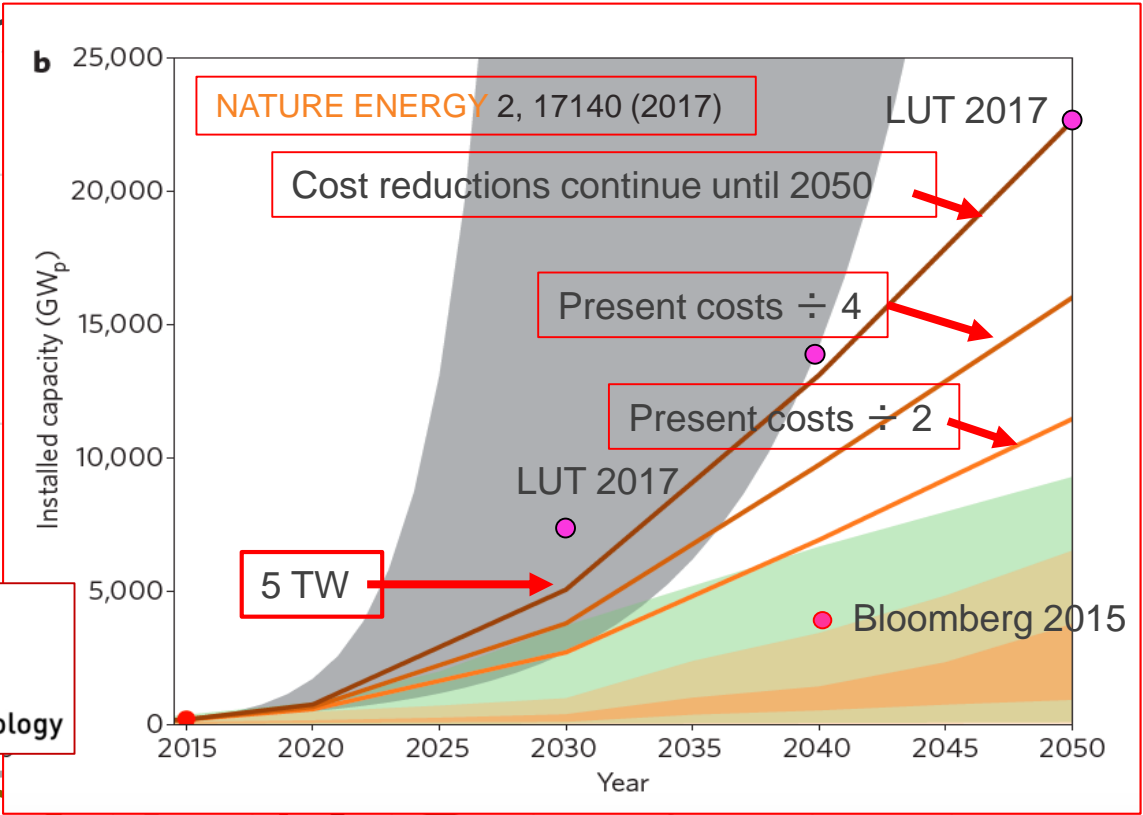
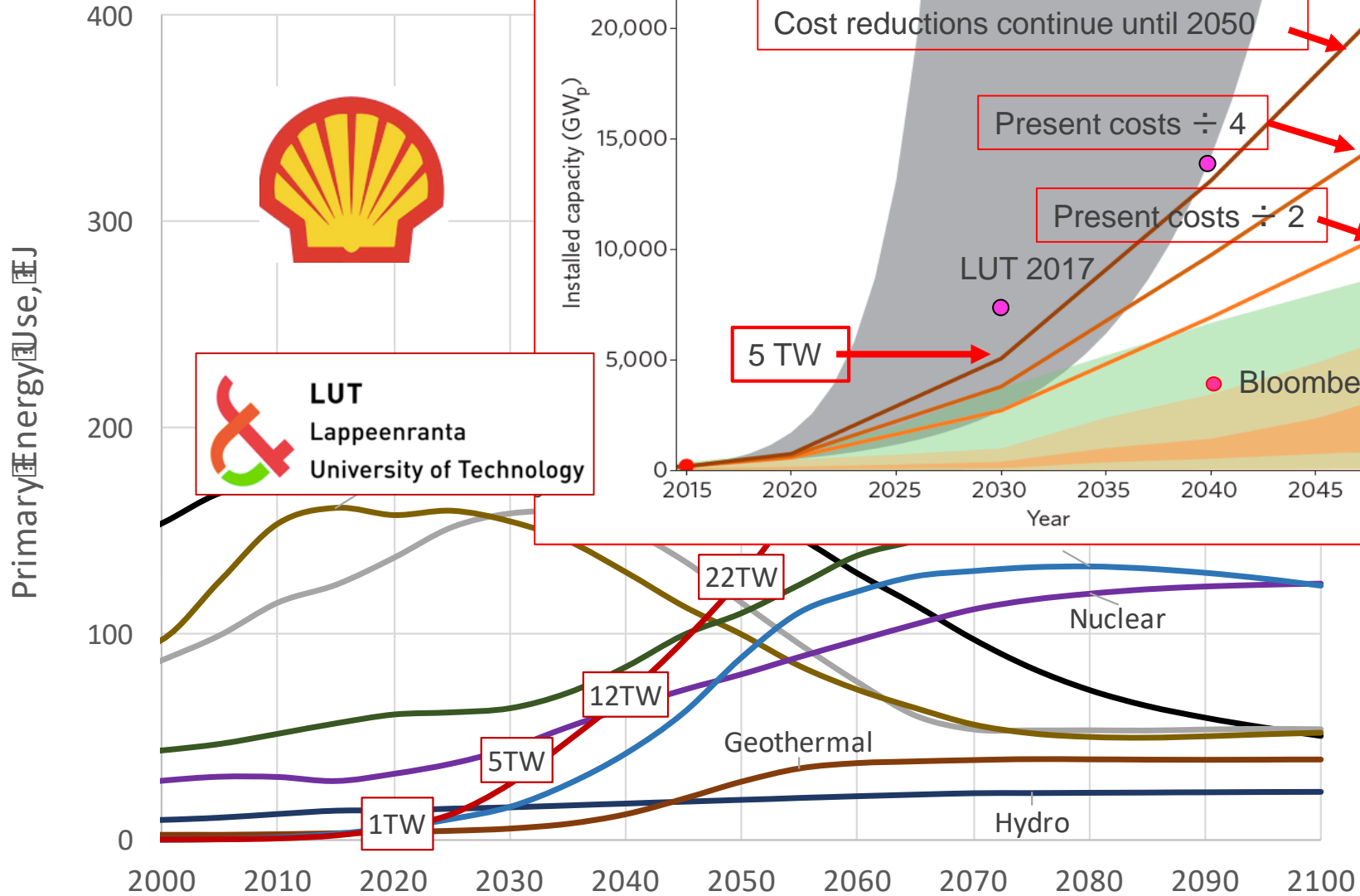
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# Primary energy use in



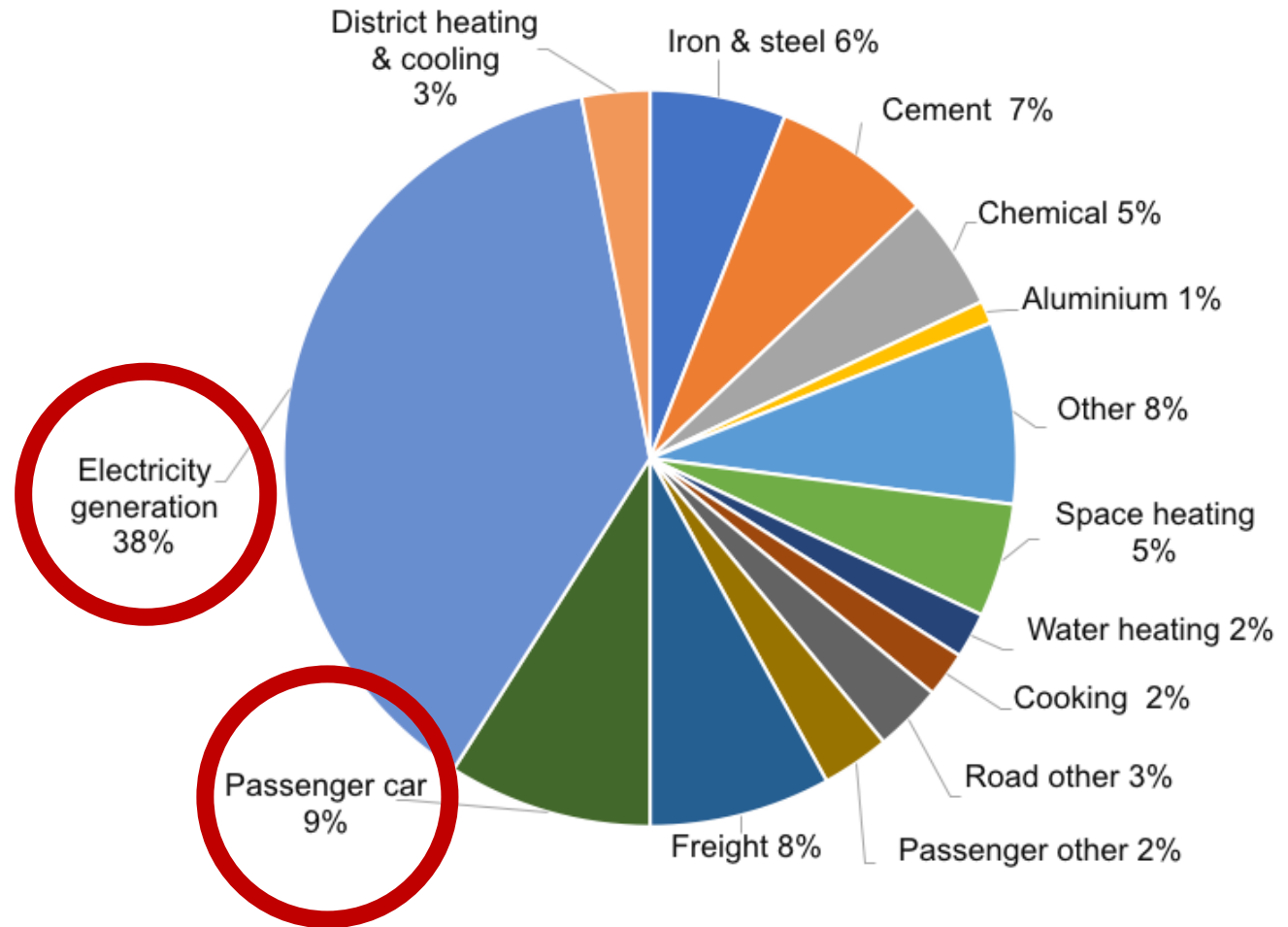
Includes waste energy oil, coal, gas, bioenergy, nuclear; only generated energy wind, solar

# Primary energy use in



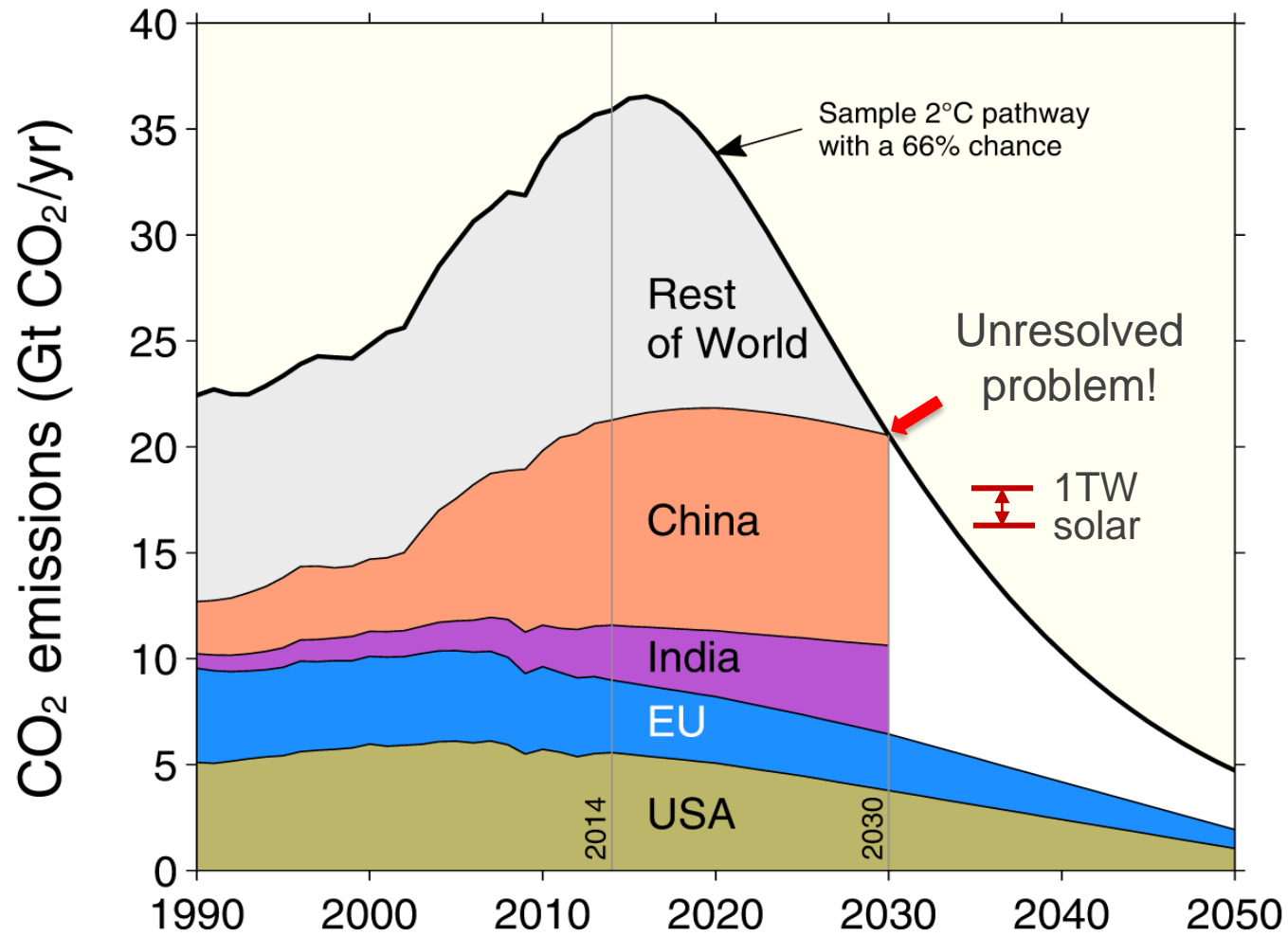
Includes waste energy oil, coal, gas, bioenergy, nuclear; only generated energy wind, solar

# Source of global CO<sub>2</sub> emissions

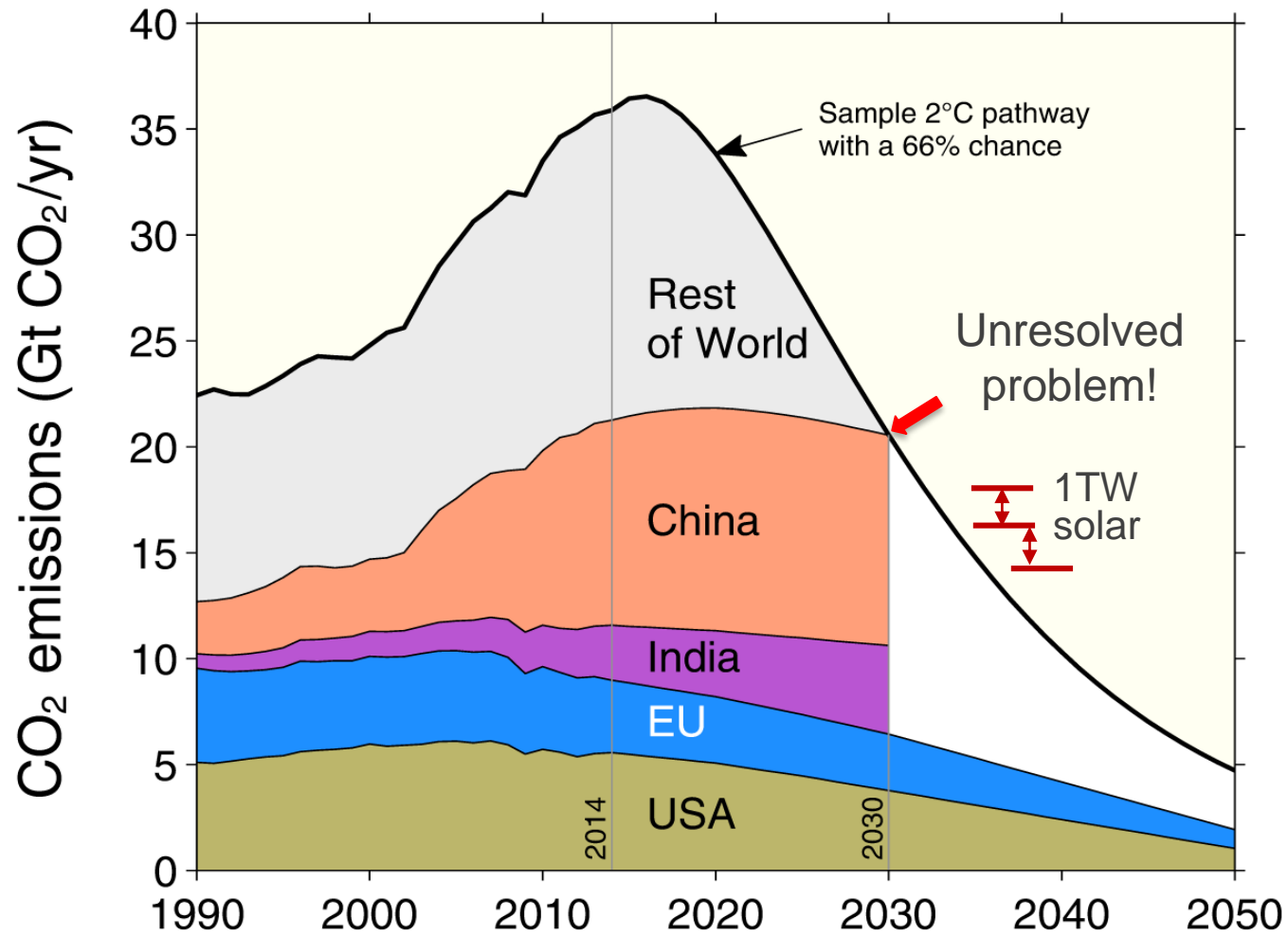




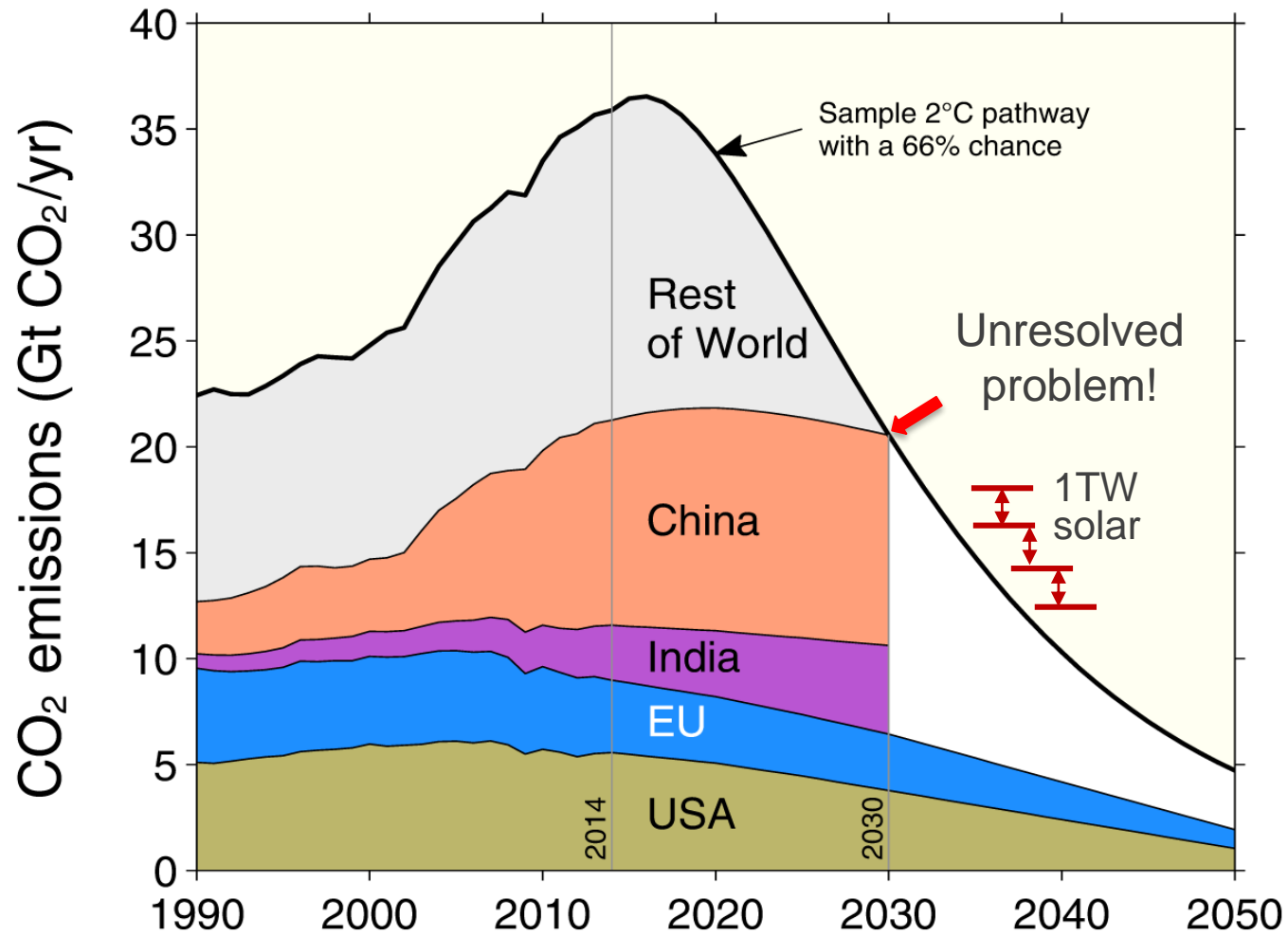
# 2°C trajectory



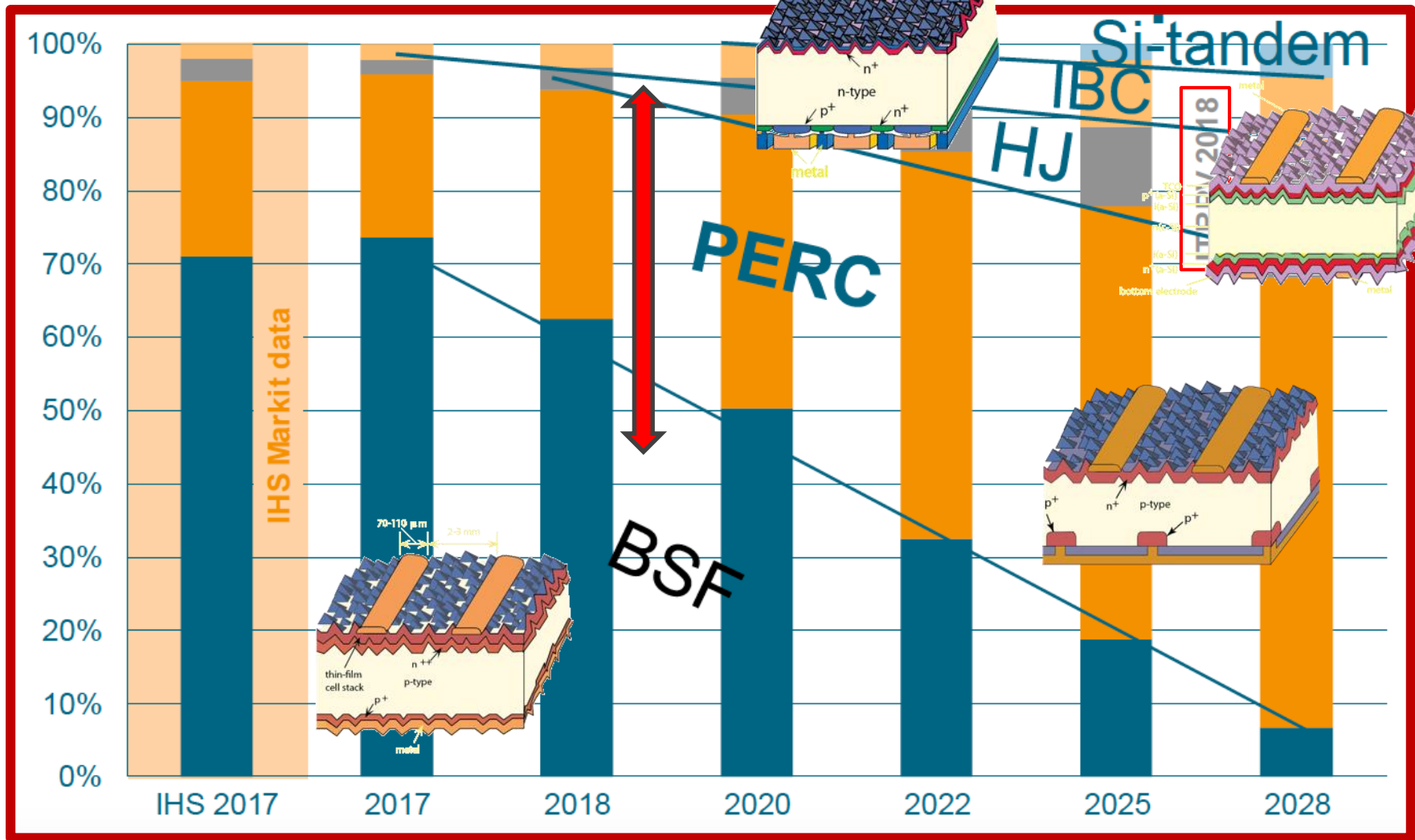
# 2°C trajectory



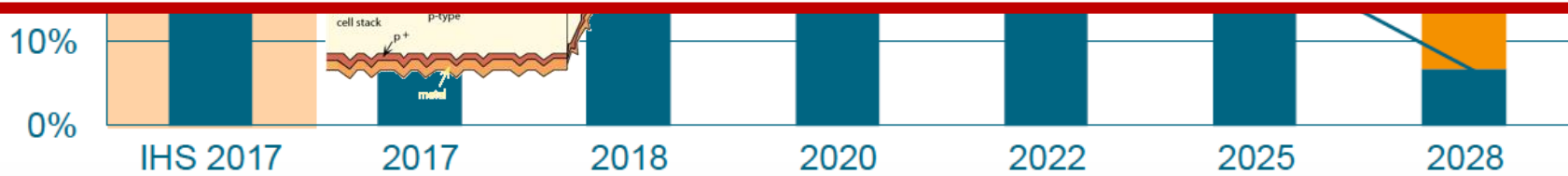
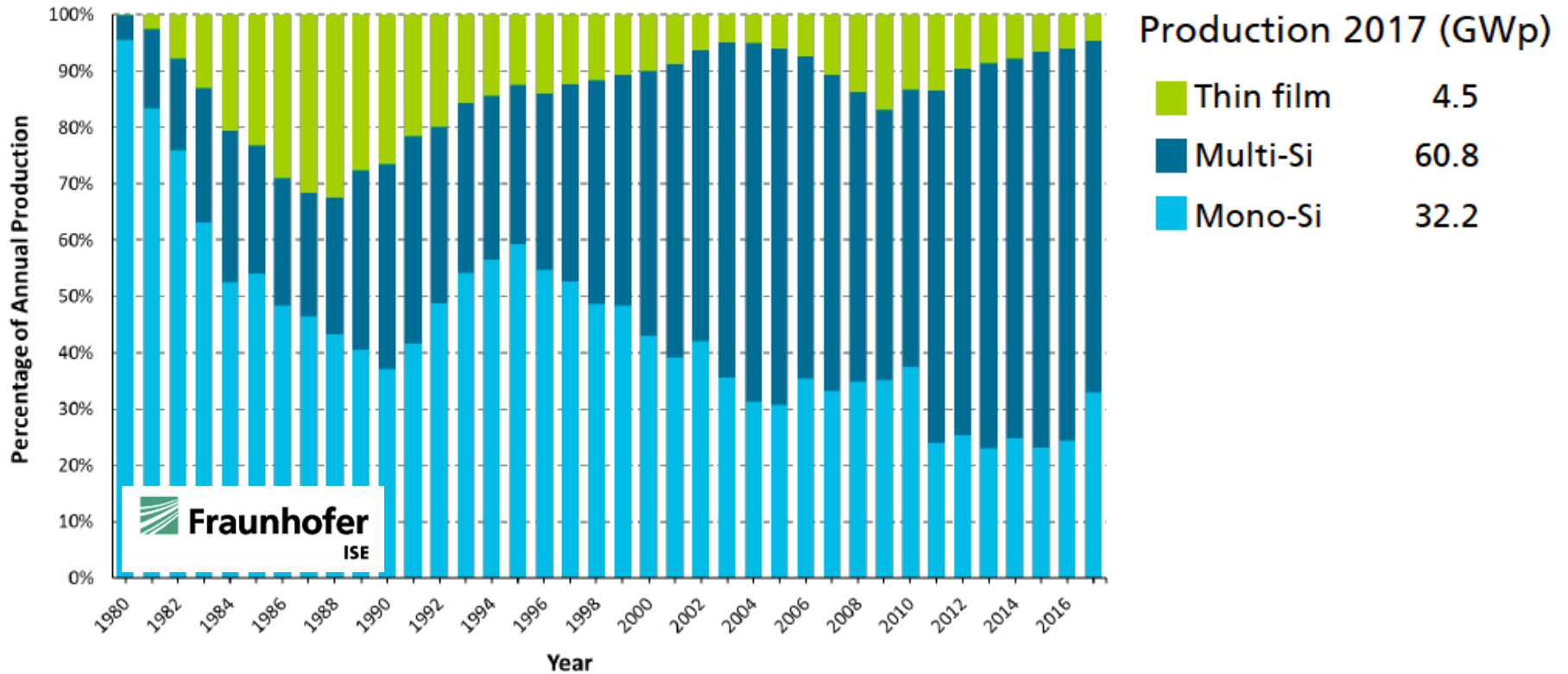
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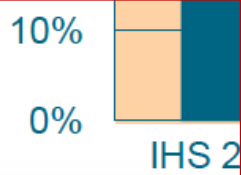
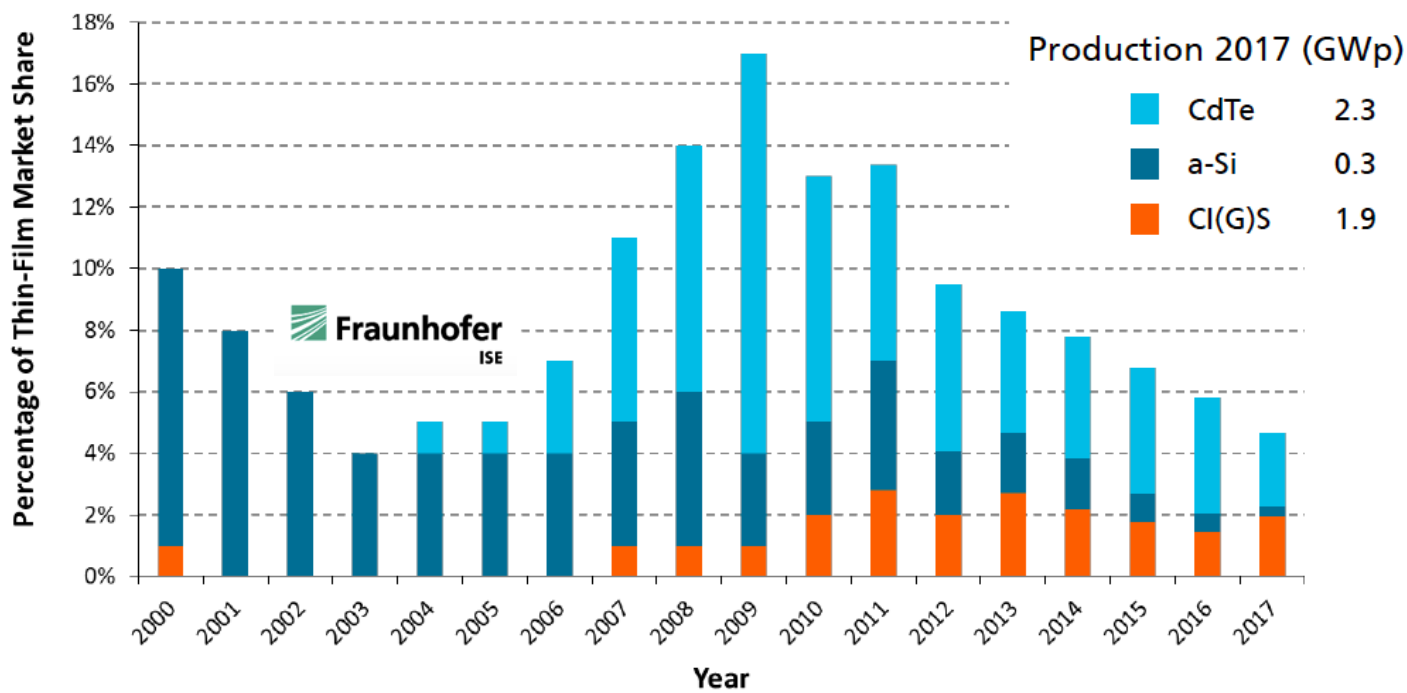
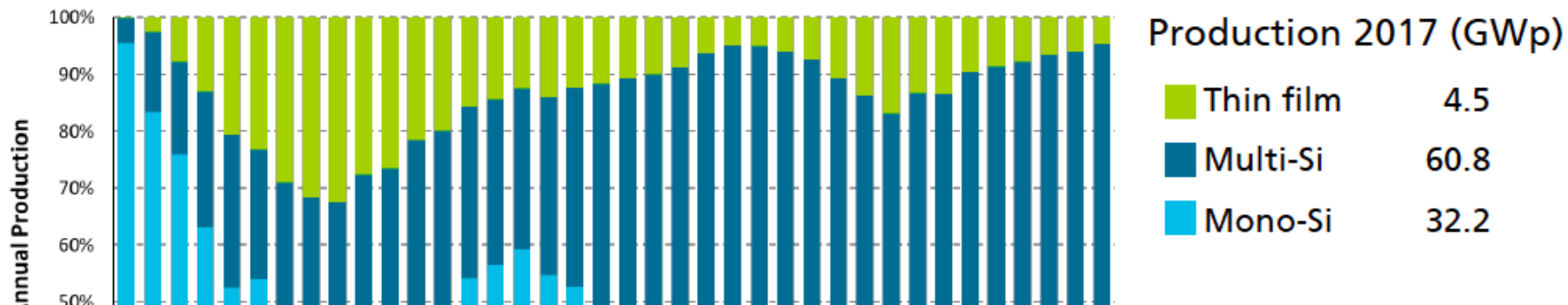
# Near-term technologies



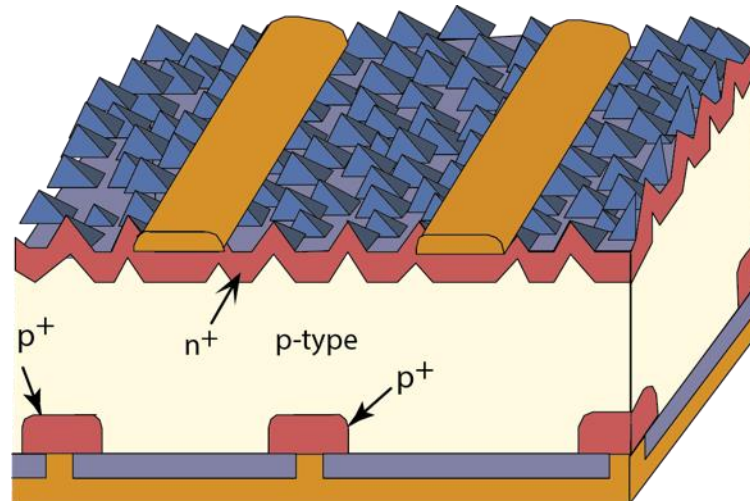
# Near-term technologies



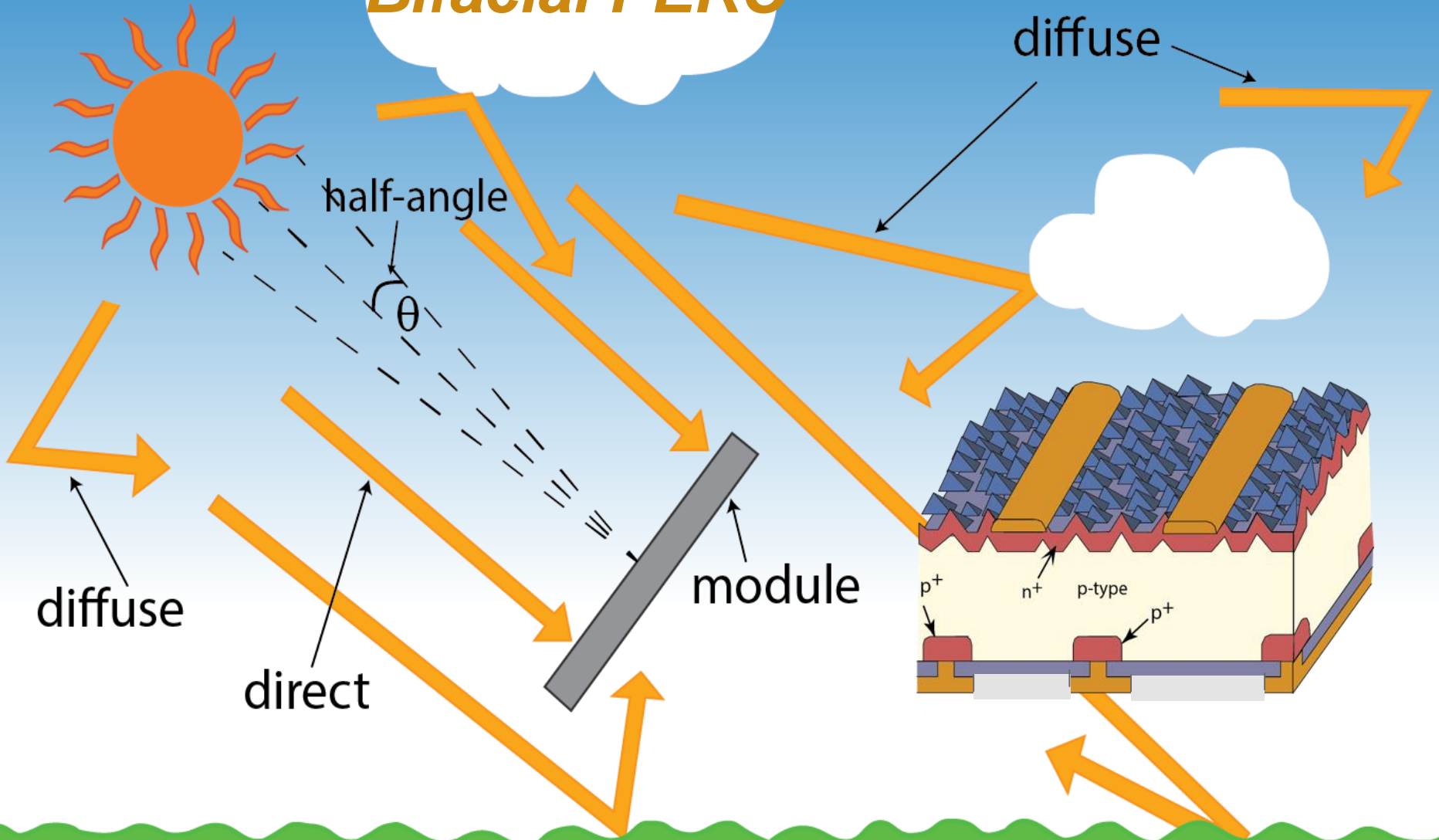
# Near-term technologies



# What comes after PERC?

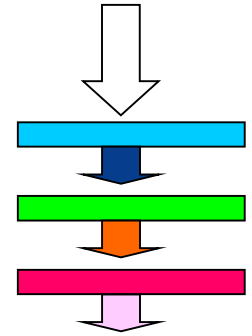
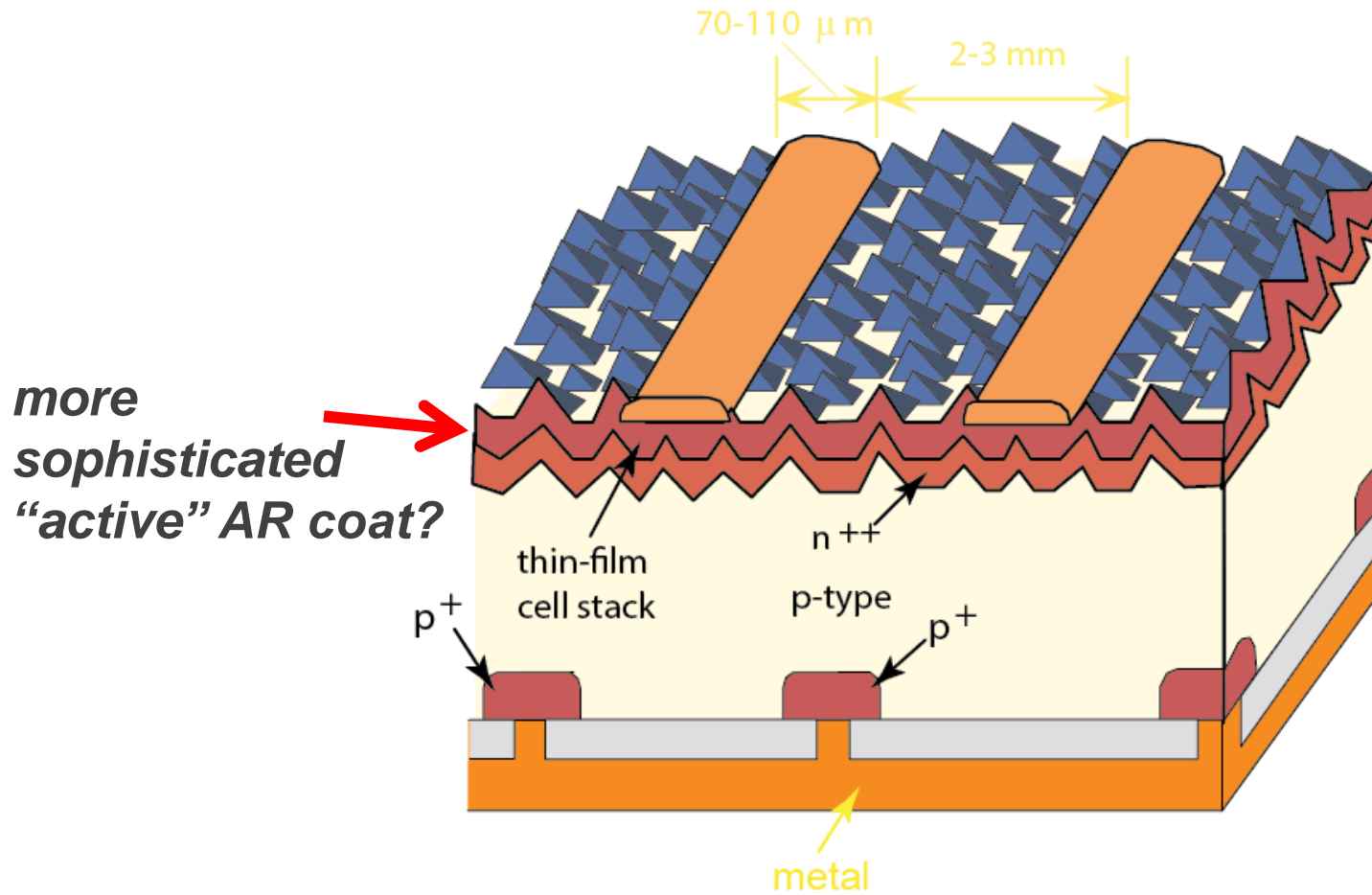


# Bifacial PERC



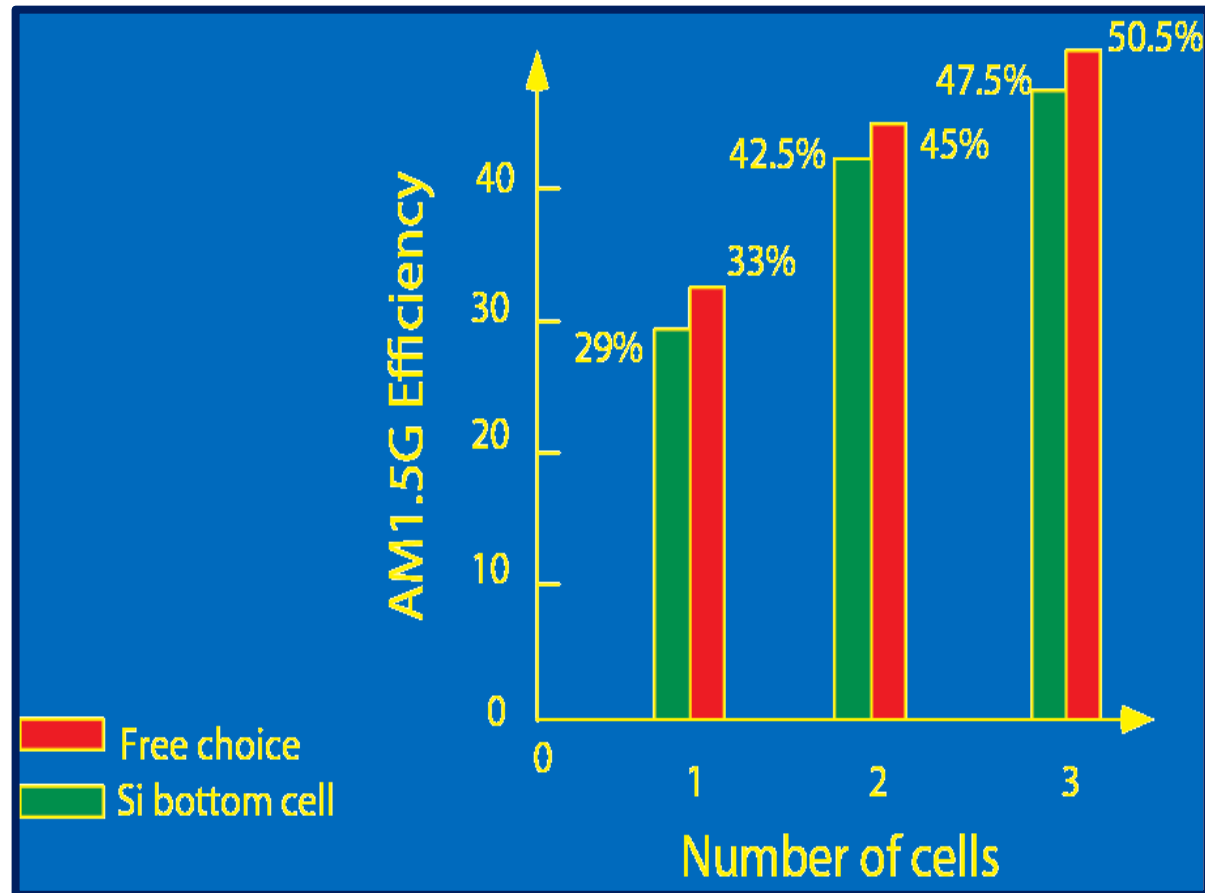
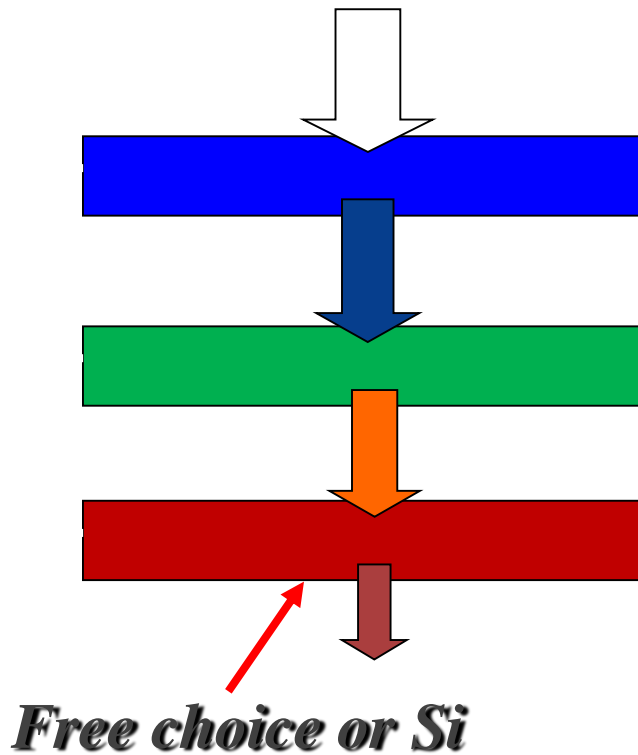


# What comes next?

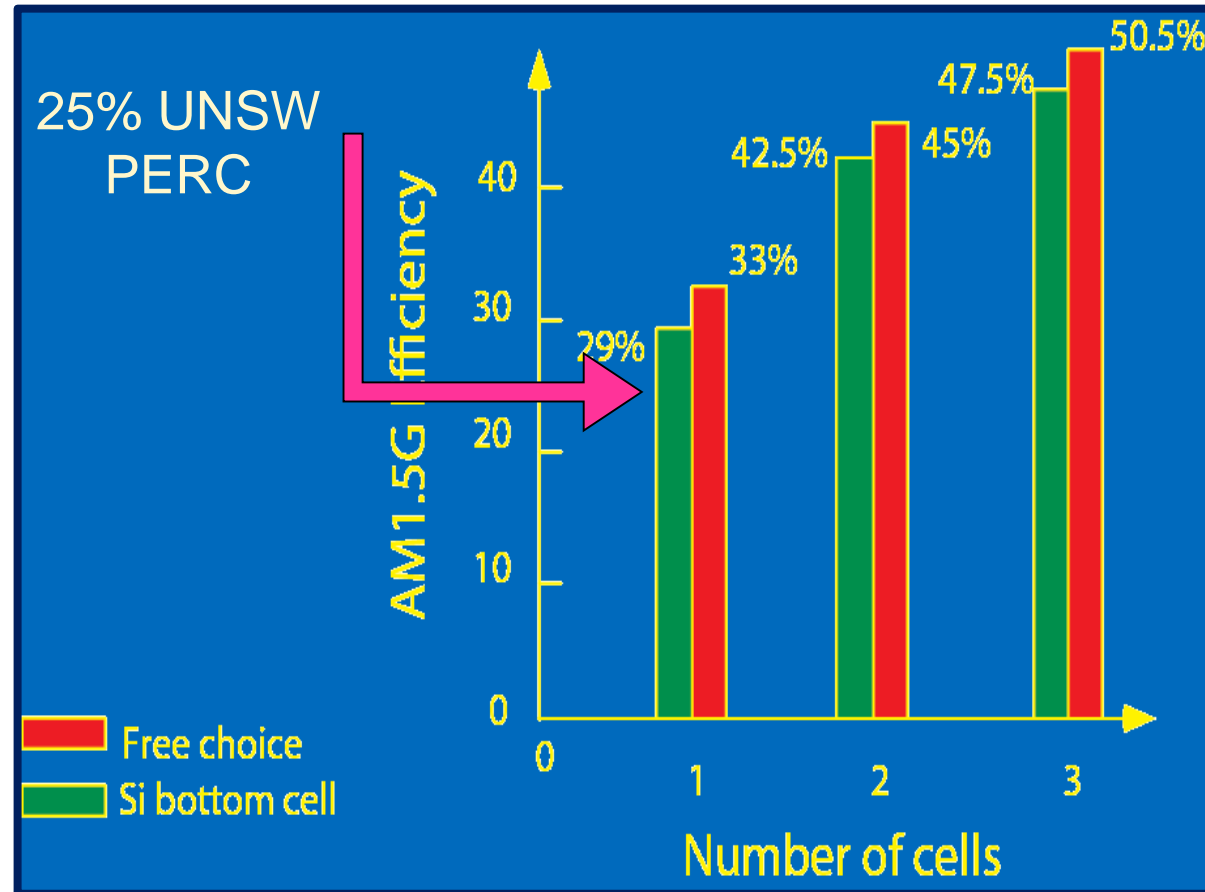
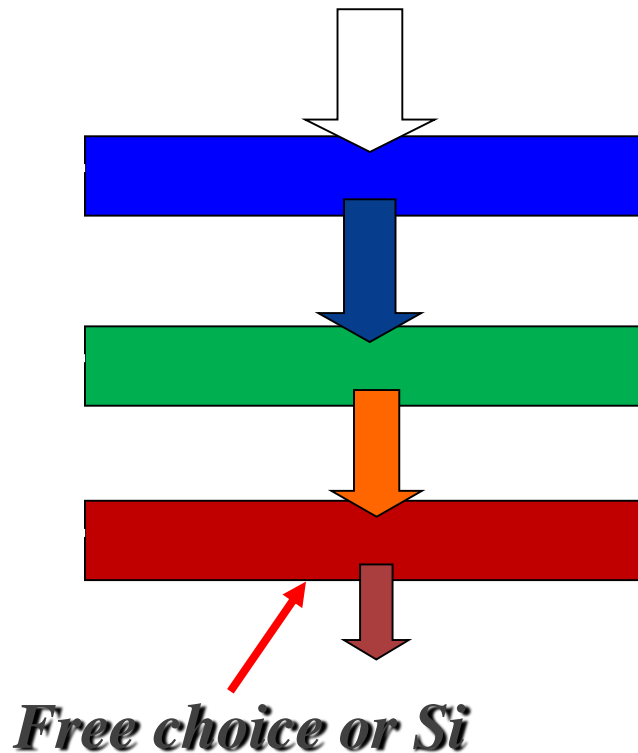


**Supercharged PERC!**

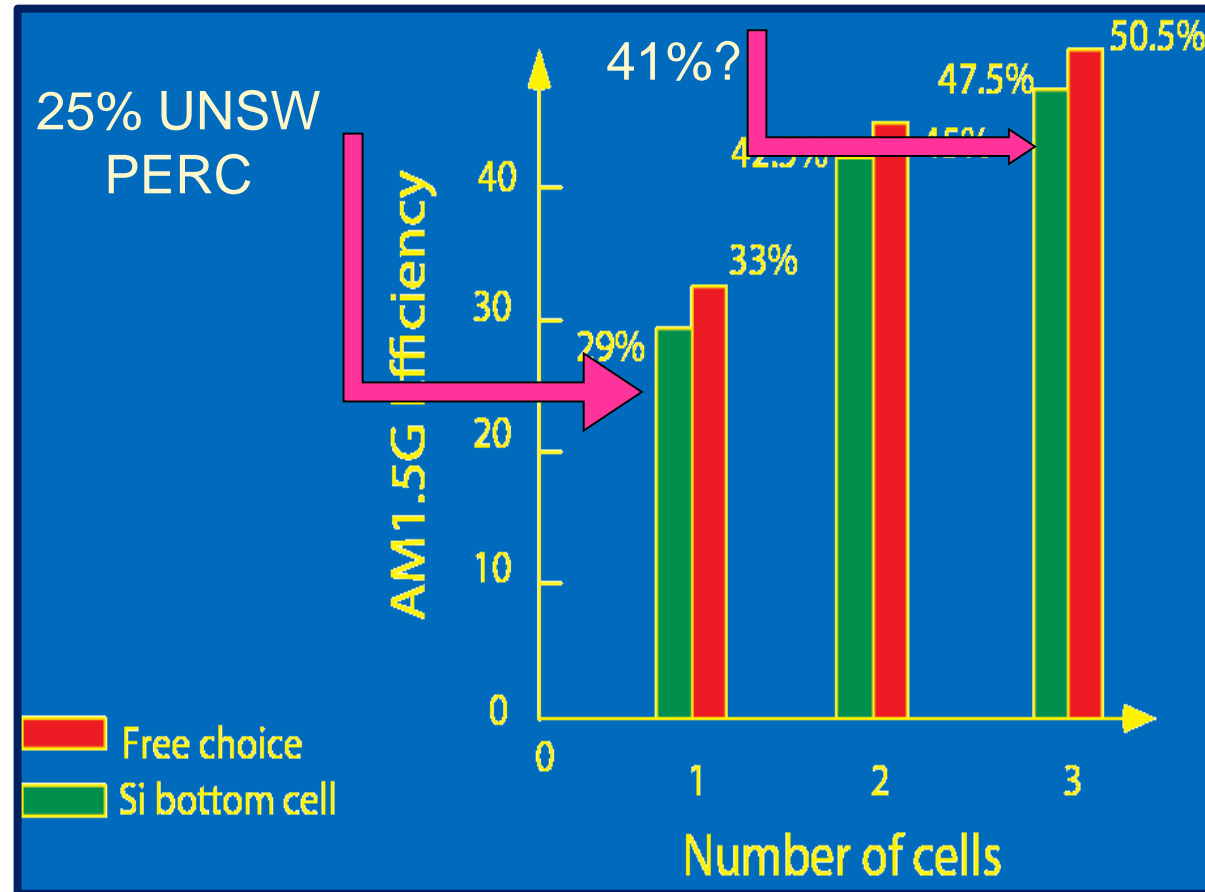
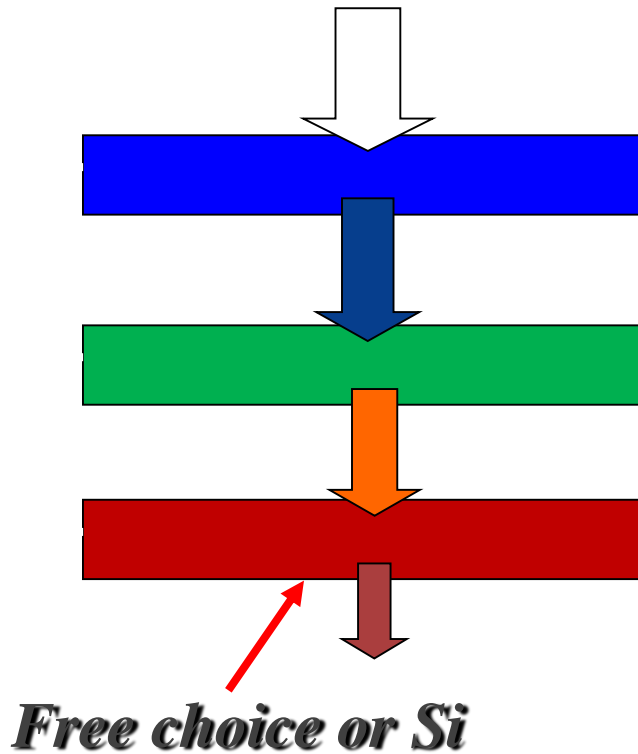
# What comes after PERC?



# Next 10 years: What comes after PERC?



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# What comes after PERC?

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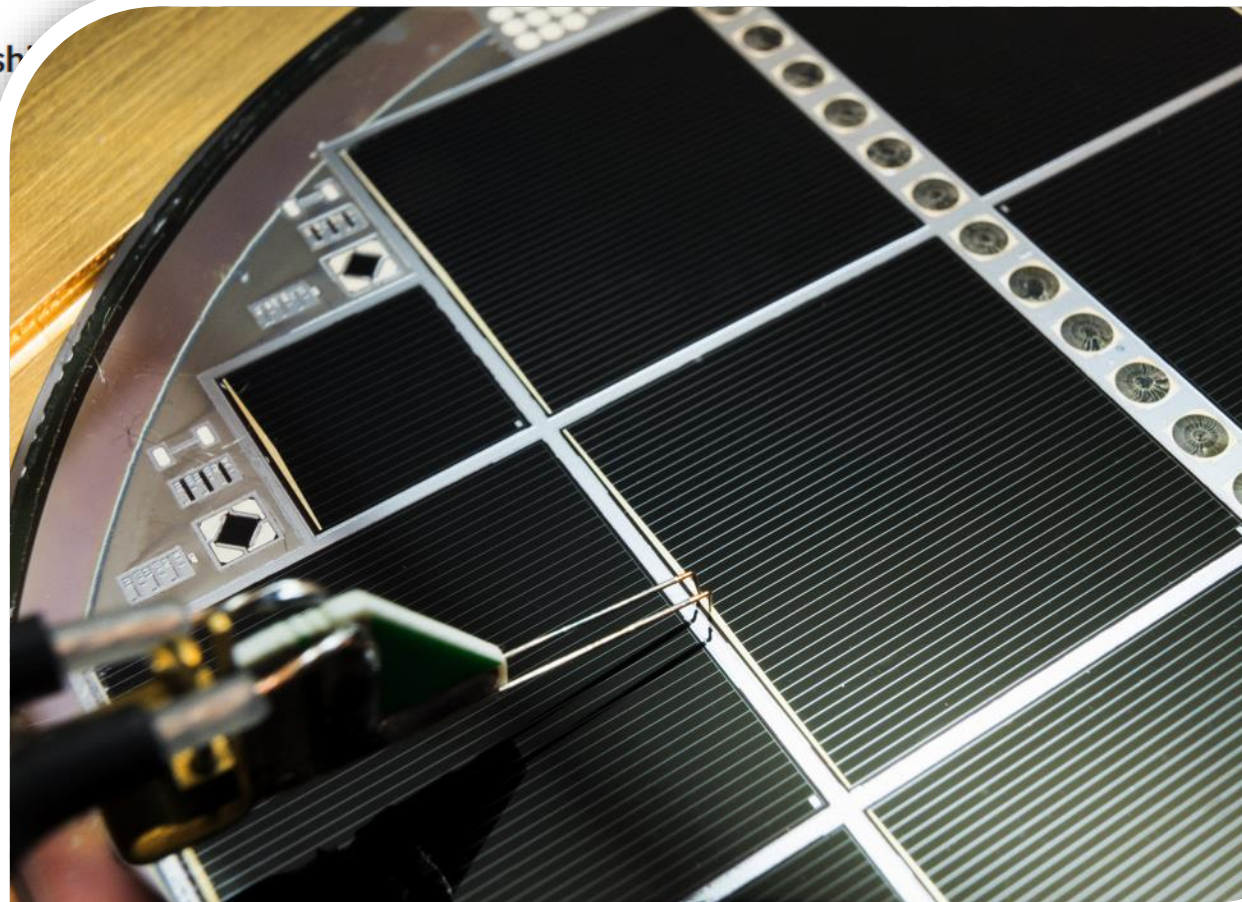
WILEY **PROGRESS IN PHOTOVOLTAICS**

## Solar cell efficiency tables (version 53)

Martin A. Green<sup>1</sup> | Yoshitaka  
Jochen Hohl-Ebinger<sup>5</sup> | A

**TABLE 3**  
25°C (IEC

Classification	Efficiency (%)
<u>III-V multijunctions</u>	
5 Junction cell (bonded) (2.17/1.68/1.40/1.06/0.73 eV)	38.8 ± 1.2
InGaP/GaAs/InGaAs	37.9 ± 1.2
GaInP/GaAs (monolithic)	32.8 ± 1.4
<u>Multijunctions with c-Si</u>	
GaInP/GaAs/Si (mech. stack)	35.9 ± 0.5 <sup>c</sup>
<b>GaInP/GaAs/Si (wafer bonded)</b>	<b>33.3 ± 1.2<sup>c</sup></b>
GaAsP/Si (monolithic)	20.1 ± 1.3
GaAs/Si (mech. stack)	32.8 ± 0.5 <sup>c</sup>
Perovskite/Si (monolithic)	25.2 ± 0.7 <sup>f</sup>
Perovskite/Si (monolithic)	27.3 ± 0.8 <sup>f</sup>
GaInP/GaInAs/Ge; Si (spectral split minimodule)	34.5 ± 2.0



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\$\$\$\$\$

Expensive

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**Ga scarce; As toxic**  
**Expensive**  
**\$\$\$\$**



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## Solar cell efficiency tables (version 53)

Martin A. Green<sup>1</sup> | Yoshihiro H  
Jochen Hohl-Ebinger<sup>5</sup> | Anita W.

Stanford  
University



23.6%  
(now 27.3%)

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25°C (IEC

Classification	Efficiency (%)	Area (cm <sup>2</sup> )
<u>III-V multijunctions</u>		
5 Junction cell (bonded) (2.17/1.68/1.40/1.06/0.73 eV)	38.8 ± 1.2	1.021 (ap)
InGaP/GaAs/InGaAs	37.9 ± 1.2	1.047 (ap)
GaInP/GaAs (monolithic)	32.8 ± 1.4	1.000 (ap)
<u>Multijunctions with c-Si</u>		
GaInP/GaAs/Si (mech. stack)	35.9 ± 0.5 <sup>c</sup>	1.002 (da)
GaInP/GaAs/Si (wafer bonded)	33.3 ± 1.2 <sup>c</sup>	3.984 (ap)
GaAsP/Si (monolithic)	20.1 ± 1.3	3.940 (ap)
GaAs/Si (mech. stack)	32.8 ± 0.5 <sup>c</sup>	1.003 (da)
Perovskite/Si (monolithic)	25.2 ± 0.7 <sup>f</sup>	1.419 (da)
<b>Perovskite/Si (monolithic)</b>	<b>27.3 ± 0.8<sup>f</sup></b>	1.088 (da)
GaInP/GaInAs/Ge; Si (spectral split minimodule)	34.5 ± 2.0	27.83 (ap)

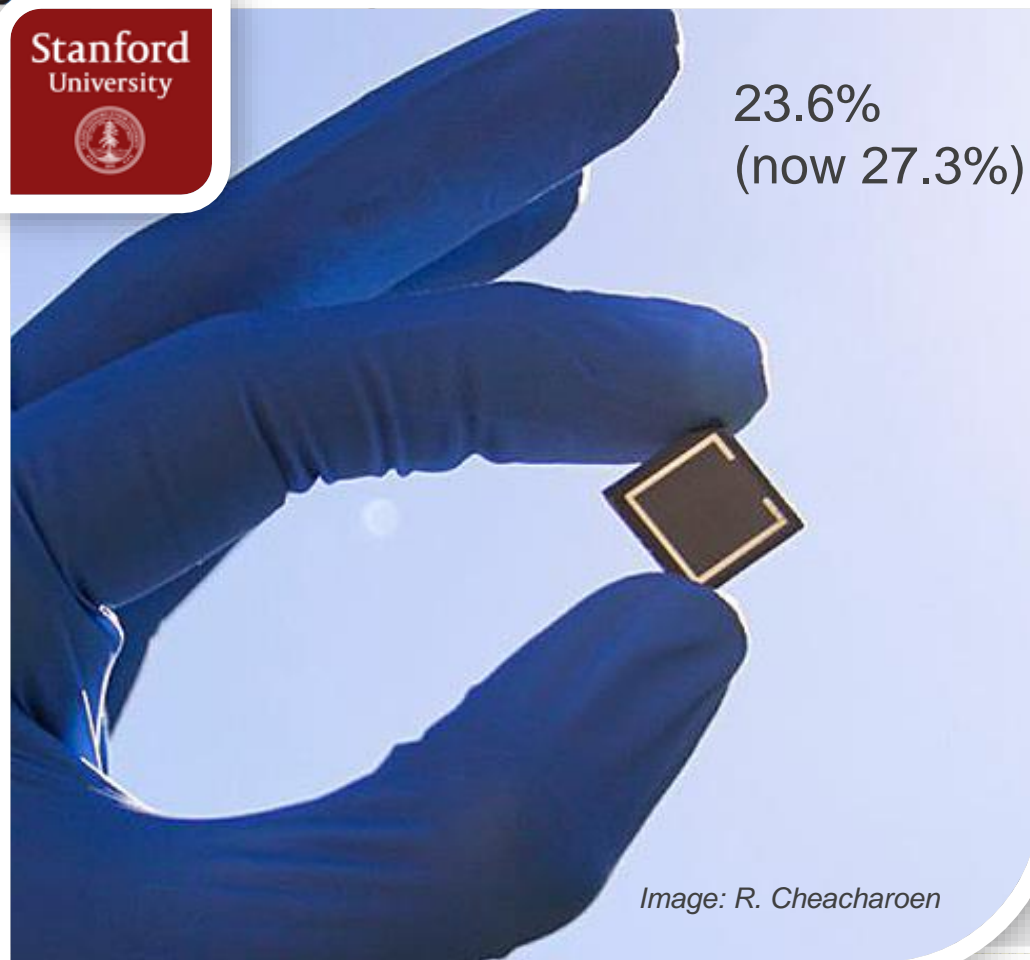


Image: R. Cheacharoen



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Jochen Hohl-Ebinger<sup>5</sup> | Anita W. Bett<sup>1</sup>



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23.6%  
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Image: R. Cheacharoen

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## Solar energy tables (version 53)

Martin A. Green<sup>1</sup>  
Jochen Hohl-Ebinger<sup>2</sup>

Stanford University



23.6%  
(now 27.3%)

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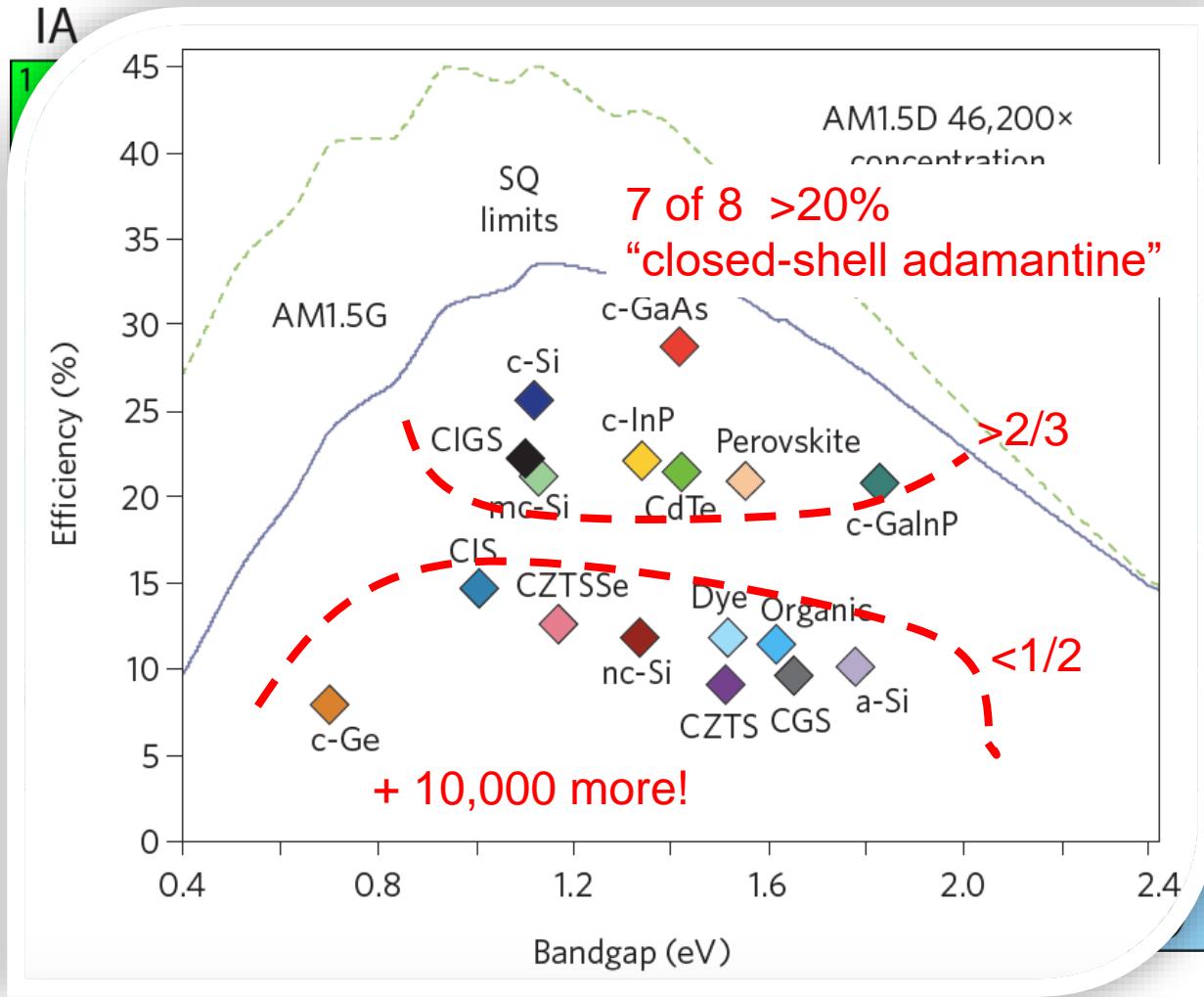


Image: R. Cheacharoen

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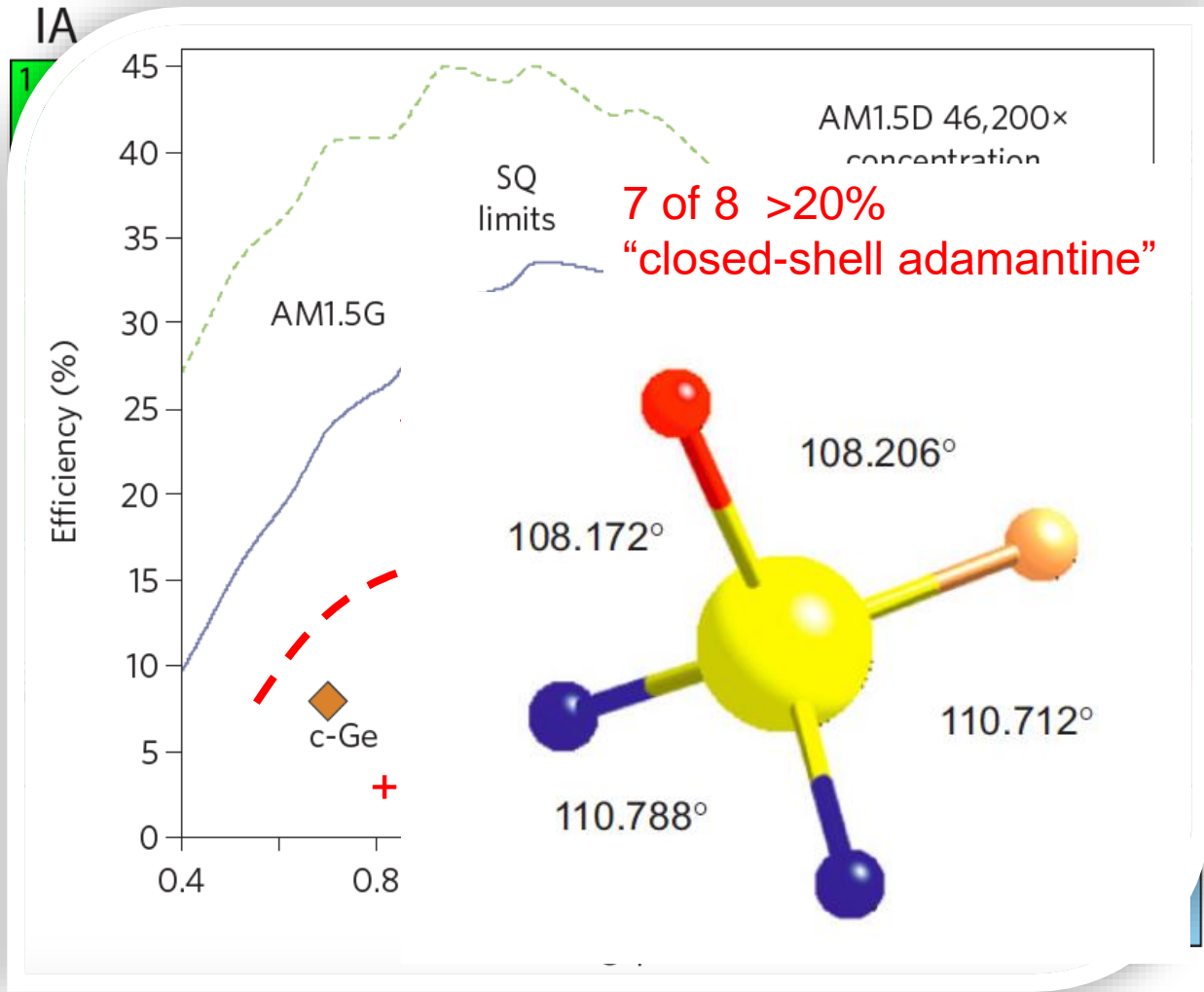
IA																							VIII B
1 <b>H</b>																	4 <b>Be</b>	5 <b>B</b>	6 <b>C</b>	7 <b>N</b>	8 <b>O</b>	9 <b>F</b>	10 <b>Ne</b>
3 <b>Li</b>																	12 <b>Mg</b>	13 <b>Al</b>	14 <b>Si</b>	15 <b>P</b>	16 <b>S</b>	17 <b>Cl</b>	18 <b>Ar</b>
11 <b>Na</b>	IIA	IIIA	IVA	VA	VIA	VIIA	VIII A			IB	30 <b>Zn</b>	31 <b>Ga</b>	32 <b>Ge</b>	33 <b>As</b>	34 <b>Se</b>	35 <b>Br</b>	36 <b>Kr</b>						
19 <b>K</b>	20 <b>Ca</b>	21 <b>Sc</b>	22 <b>Ti</b>	23 <b>V</b>	24 <b>Cr</b>	25 <b>Mn</b>	26 <b>Fe</b>	27 <b>Co</b>	28 <b>Ni</b>	29 <b>Cu</b>	30 <b>Zn</b>	31 <b>Ga</b>	32 <b>Ge</b>	33 <b>As</b>	34 <b>Se</b>	35 <b>Br</b>	36 <b>Kr</b>						
37 <b>Rb</b>	38 <b>Sr</b>	39 <b>Y</b>	40 <b>Zr</b>	41 <b>Nb</b>	42 <b>Mo</b>	43 <b>Tc</b>	44 <b>Ru</b>	45 <b>Rh</b>	46 <b>Pd</b>	47 <b>Ag</b>	48 <b>Cd</b>	49 <b>In</b>	50 <b>Sn</b>	51 <b>Sb</b>	52 <b>Te</b>	53 <b>I</b>	54 <b>Xe</b>						
55 <b>Cs</b>	56 <b>Ba</b>	57-71 <b>Lanthanides</b>	72 <b>Hf</b>	73 <b>Ta</b>	74 <b>W</b>	75 <b>Re</b>	76 <b>Os</b>	77 <b>Ir</b>	78 <b>Pt</b>	79 <b>Au</b>	80 <b>Hg</b>	81 <b>Tl</b>	82 <b>Pb</b>	83 <b>Bi</b>	84 <b>Po</b>	85 <b>At</b>	86 <b>Rn</b>						
			57 <b>La</b>	58 <b>Ce</b>	59 <b>Pr</b>	60 <b>Nd</b>	61 <b>Pm</b>	62 <b>Sm</b>	63 <b>Eu</b>	64 <b>Gd</b>	65 <b>Tb</b>	66 <b>Dy</b>	67 <b>Ho</b>	68 <b>Er</b>	69 <b>Tm</b>	70 <b>Yb</b>	71 <b>Lu</b>						

# What comes after PERC?



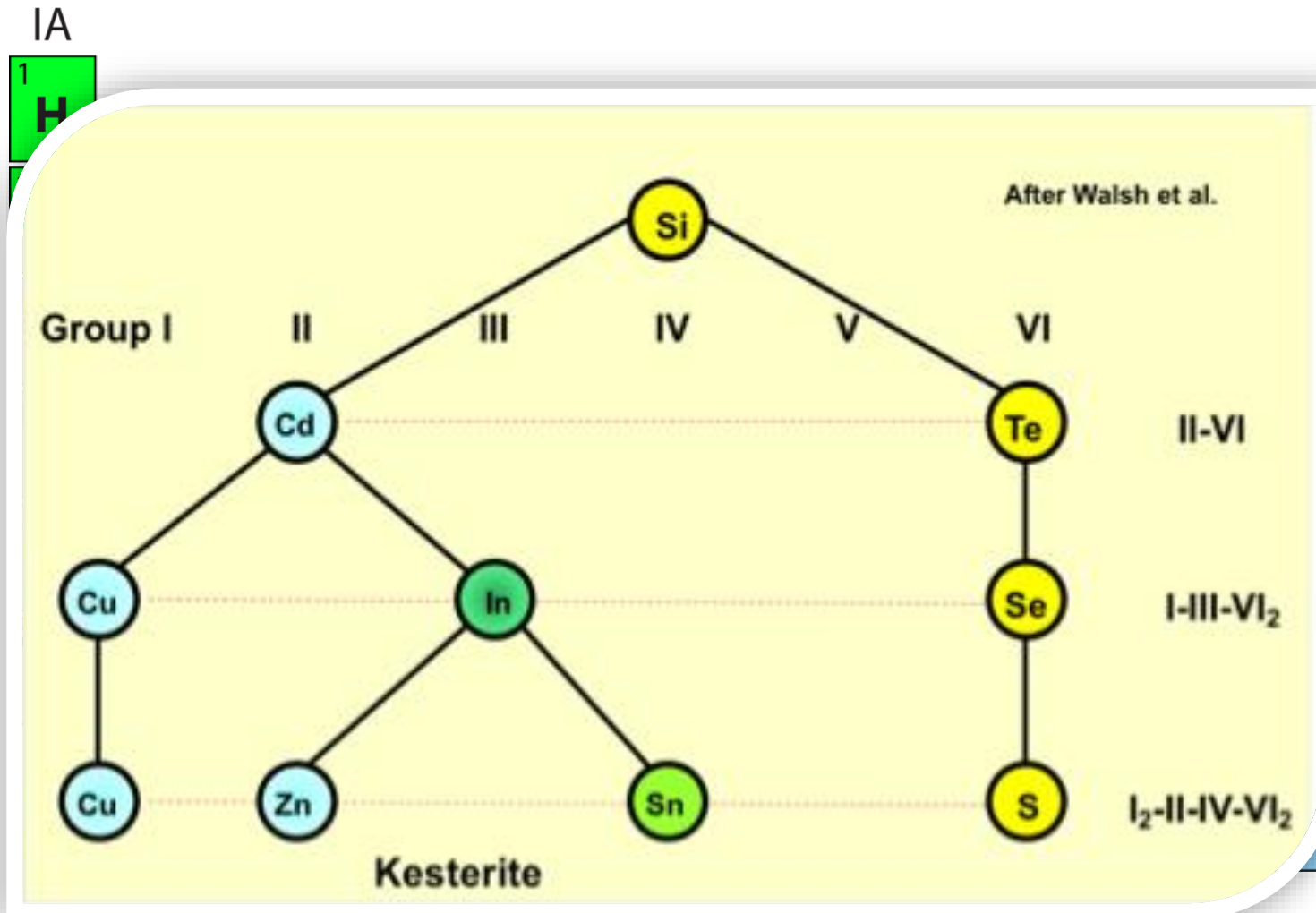
					VIIIB	2
						He
IIIB	IVB	VB	VIB	VIIIB		
5	6	7	8	9	10	
B	C	N	O	F	Ne	
13	14	15	16	17	18	
Al	Si	P	S	Cl	Ar	
31	32	33	34	35	36	
Ga	Ge	As	Se	Br	Kr	
49	50	51	52	53	54	
In	Sn	Sb	Te	I	Xe	
81	82	83	84	85	86	
Tl	Pb	Bi	Po	At	Rn	
67	68	69	70	71		
Ho	Er	Tm	Yb	Lu		

# What comes after PERC?



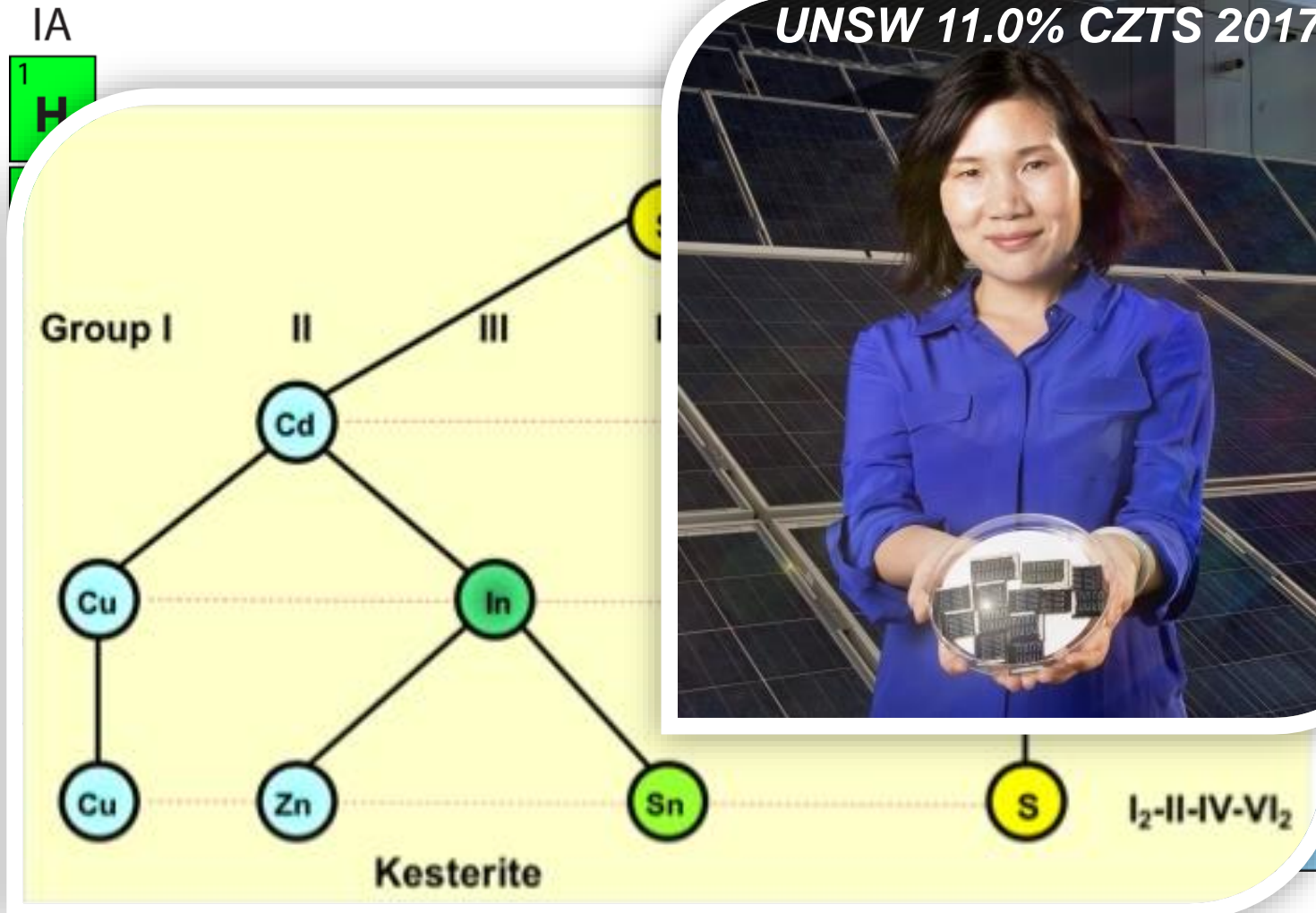
					VIIIB
					2
					<b>He</b>
IIIB	IVB	VB	VIB	VIIIB	
5	6	7	8	9	10
<b>B</b>	<b>C</b>	<b>N</b>	<b>O</b>	<b>F</b>	<b>Ne</b>
13	14	15	16	17	18
<b>Al</b>	<b>Si</b>	<b>P</b>	<b>S</b>	<b>Cl</b>	<b>Ar</b>
31	32	33	34	35	36
<b>Ga</b>	<b>Ge</b>	<b>As</b>	<b>Se</b>	<b>Br</b>	<b>Kr</b>
49	50	51	52	53	54
<b>In</b>	<b>Sn</b>	<b>Sb</b>	<b>Te</b>	<b>I</b>	<b>Xe</b>
81	82	83	84	85	86
<b>Tl</b>	<b>Pb</b>	<b>Bi</b>	<b>Po</b>	<b>At</b>	<b>Rn</b>
67	68	69	70	71	
<b>Ho</b>	<b>Er</b>	<b>Tm</b>	<b>Yb</b>	<b>Lu</b>	

# What comes after PERC?



			VIIIB
			2
			<b>He</b>
			10
			<b>Ne</b>
			18
			<b>Ar</b>
			36
			<b>Kr</b>
			54
			<b>Xe</b>
			86
			<b>Rn</b>
			70
			<b>Yb</b>
			71
			<b>Lu</b>

# What comes after PERC?



		VIIIB	2
			He
VIB		VIIIB	
3	9		10
O	F		Ne
6	17		18
S	Cl		Ar
4	35		36
Se	Br		Kr
2	53		54
Te	I		Xe
84	85		86
Po	At		Rn
	70	71	
	Yb	Lu	

# What comes after PERC?

IA  
1  
**H**

Group 0

Group I      II      III

**NZTS**

**UNSW 11.0% CZTS 2017**

VIIIB      VIIIB      VIIIB

2  
**He**

8      9      10  
**O**    **F**    **Ne**

16      17      18  
**S**    **Cl**    **Ar**

34      35      36  
**Se**   **Br**    **Kr**

52      53      54  
**Te**   **I**      **Xe**

84      85      86  
**Po**   **At**    **Rn**

70      71  
**Yb**   **Lu**

**0-II<sub>2</sub>-IV-VI<sub>2</sub>**



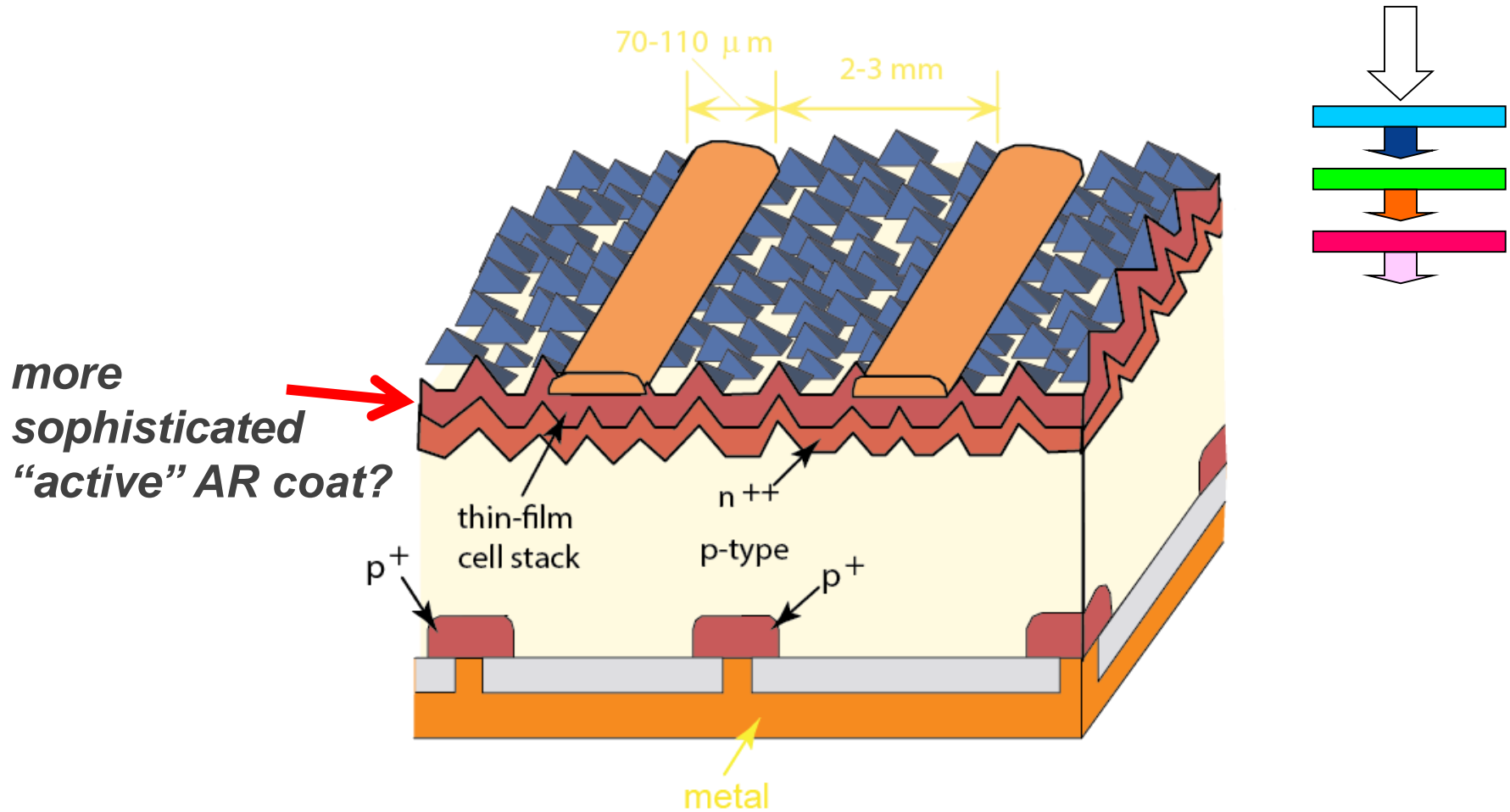
# What comes after PERC?

Table 1: Families of Potential Closed-Shell Adamantine Semiconductors

		BINARY	TERNARY	QUATERNARY	QUINTERNARY	
IA 1 <b>H</b>		<i>I-VII</i>	$(I_2-VII_2)$	$0-II-VII_2$	<b>Halides</b>	
			$(I_3-VII_3)^*$	$(0_2-III-VII_3)$		$(0-I-II-VII_3)$
3 <b>Li</b>			$(I_4-VII_4)$	$0_3-IV-VII_4$		$0-I_2-II-VII_4$
						$0_2-I-III-VII_4$
11 <b>Na</b>		<i>II-VI</i>	$(II_2-VI_2)$	$0-IV-VI_2$	<b>Chalcogenides</b>	
				$I-III-VI_2$		
19 <b>K</b>			$(III_3-VI_3)^*$	$(0-III_2-VI_3)$		$(0-I-V-VI_3)$
				$(I_2-IV-VI_3)$		$(0-II-IV-VI_3)$
37 <b>Rb</b>	<b>IV</b>			$(I-II-III-VI_3)$		
			$(III_4-VI_4)$	$I_3-V-VI_4$		$0-II-III_2-VI_4$
55 <b>Cs</b>				$0-II_2-IV-VI_4$		$0-I-III-IV-VI_4$
				$I-II_2-III-VI_4$		
				$I_2-II-IV-VI_4$		
		<i>III-V</i>	$(III_2-V_2)$	$II-IV-V_2$	<b>Pnictides</b>	
			$(III_3-V_3)^*$	$(I-IV_2-V_3)$		$(II-III-IV-V_3)$
			$(III_4-V_4)$	$0-IV_3-V_4$		$I-III-IV_2-V_4$
				$II-III_2-IV-V_4$		
		<i>IV-IV</i>	*Anions surrounded by different cation combinations			

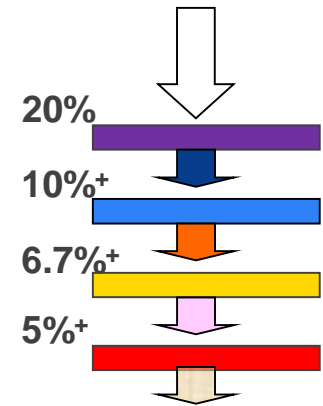
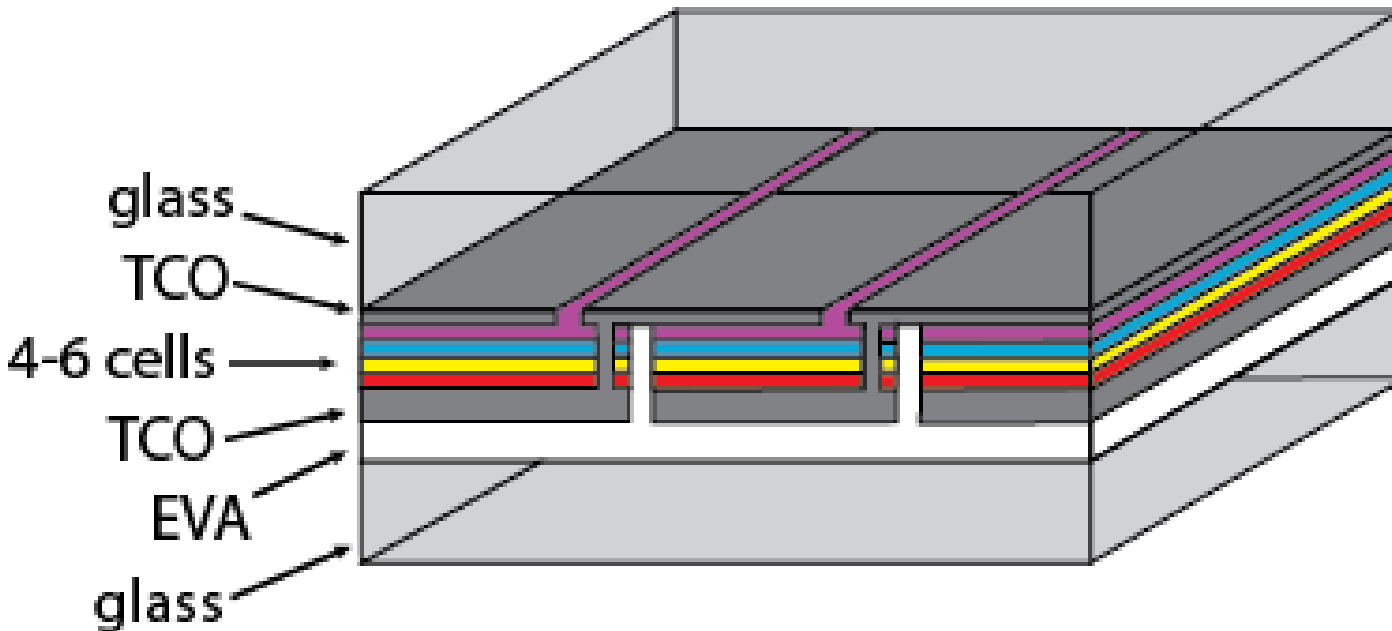


# What comes after double-junction PERC?



***Triple-junction PERC! – middle cell nearly for free!***

# What comes after triple-junction PERC?



***Quadruple-junction thin-film!***

# 'Current overview of PV technologies and PV technology visions for the future'

## 5-10 years forward:

Si continues to dominate;

PERC perfected (>25% in production)( $H_2$ );

Multicrystalline or mono? n-type grows

Higher efficiency – tandem most realistic option;

What top cell material?

Polycrystalline chalcogenide?

## 15-20 years forward:

3-cell Si based tandems

Then 4+ thin-film tandems

# Australian Centre for Advanced Photovoltaics



ARENA



Australian Government

Australian Renewable  
Energy Agency



UNSW  
SYDNEY